



EDMI Microsystems and Microelectronics

MICRO-614: Electrochemical Nano-Bio-Sensing
and Bio/CMOS interfaces

Lecture #7

Checking Probes-layer quality
(RM+SPR+SEM+AFM)

Lecture Outline

(Book Bio/CMOS: Chapter' paragraphs § 5.2.1-2)

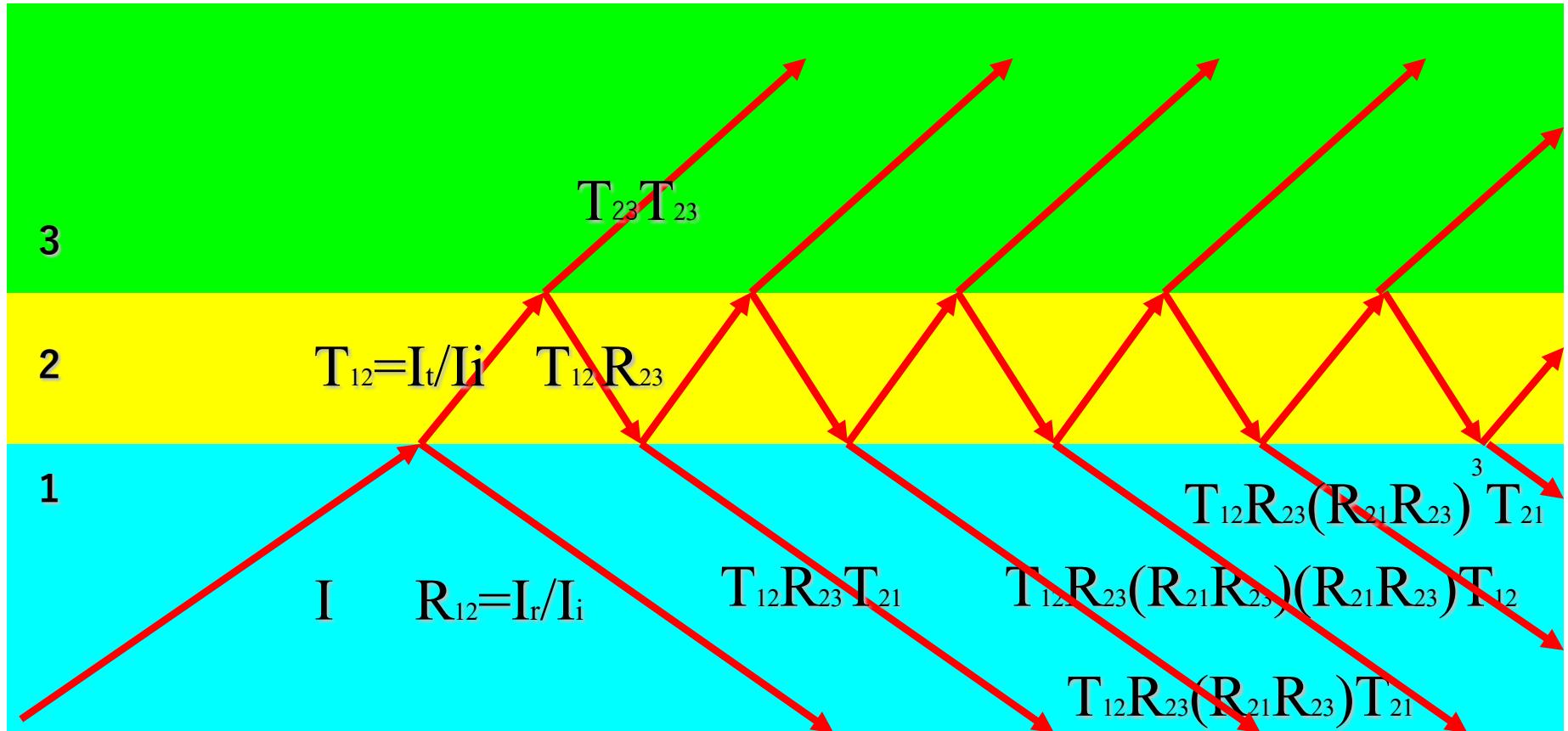
- Resonant Mirror
- Surface Plasmon Resonance

To monitor the self-assembly process

- Transmission Electron Microscopy
- Scanning Electron Microscopy
- Atomic Force Microscopy
- Scanning Tunneling Microscopy

To check the film quality

Three-layers Reflection



$$R = R_{12} + T_{12}R_{23}T_{21} + T_{12}R_{23}T_{21}(R_{21}R_{23}) + T_{12}R_{23}T_{21}(R_{21}R_{23})^2 + \dots$$

Three-layers Reflection

$$R = R_{12} + T_{12}R_{23}T_{21} + T_{12}R_{23}T_{21}(R_{21}R_{23}) + T_{12}R_{23}T_{21}(R_{21}R_{23})^2 + \dots$$

$$R = R_{12} + \sum_{n=0}^{\infty} T_{12}R_{23}T_{21}(R_{21}R_{23})^n$$

$$R = R_{12} + T_{12}R_{23}T_{21} \sum_{n=0}^{\infty} (R_{21}R_{23})^n$$

By the geometric series

$$\sum_{n=0}^{\infty} x^n = \frac{1}{1-x}$$

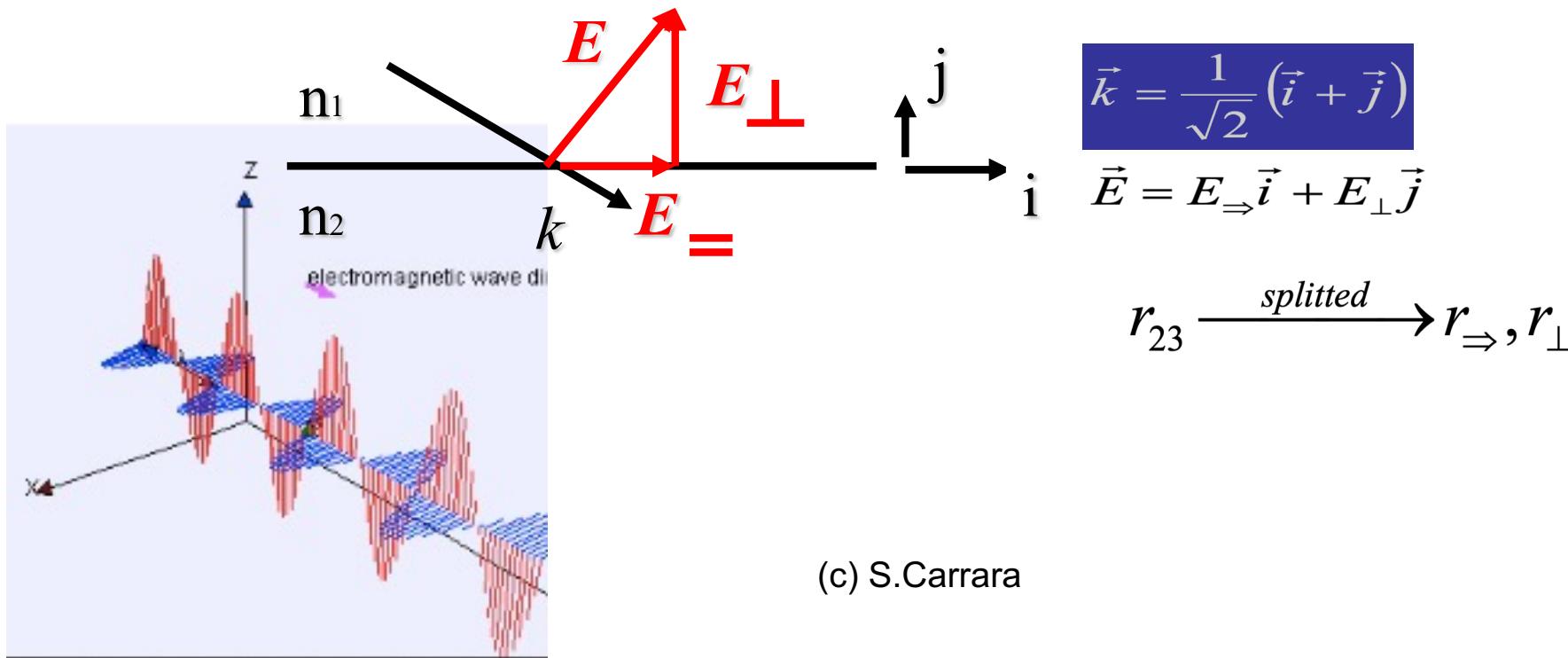
$$R = R_{12} + T_{12}R_{23}T_{21} \frac{1}{1-R_{21}R_{23}}$$

The Reflection coefficient and the Electrical Field

$$R = R_{12} + \frac{T_{12}R_{23}T_{21}}{1 - R_{21}R_{23}}$$

$$R_{23} = |r_{23}|^2$$

$$R_{23} = \frac{I_r}{I_i}; r_{23} = \frac{E_r}{E_i}$$



The Fresnel Coefficients

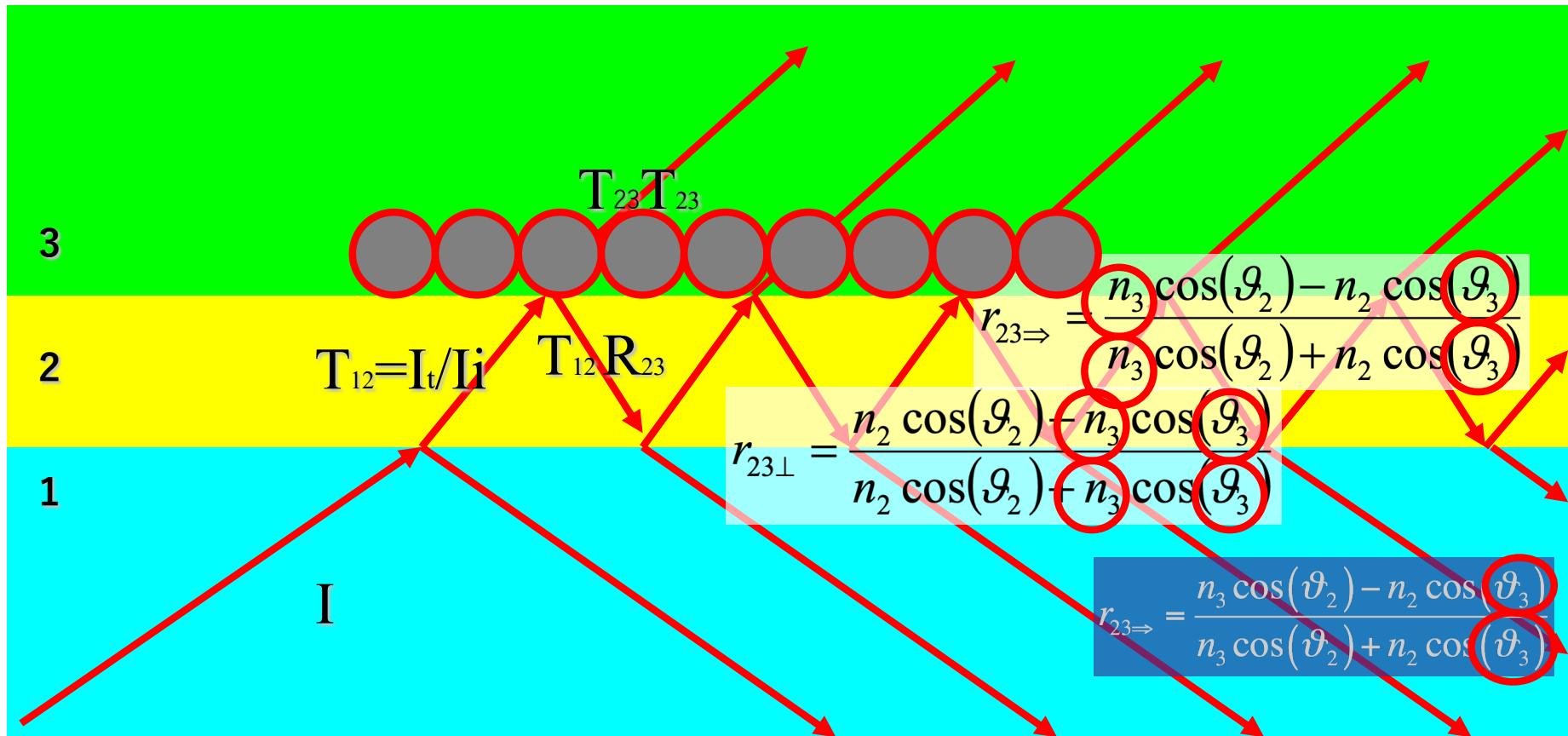
$$\begin{array}{l}
 \boxed{r_{23} \xrightarrow{\text{splitted}} r_{\Rightarrow}, r_{\perp}} \longrightarrow \boxed{r_{23\Rightarrow} = \frac{n_3 \cos(\vartheta_2) - n_2 \cos(\vartheta_3)}{n_3 \cos(\vartheta_2) + n_2 \cos(\vartheta_3)}}
 \\[10pt]
 \boxed{t_{23} \xrightarrow{\text{splitted}} t_{\Rightarrow}, t_{\perp}} \longrightarrow \boxed{r_{23\perp} = \frac{n_2 \cos(\vartheta_2) - n_3 \cos(\vartheta_3)}{n_2 \cos(\vartheta_2) + n_3 \cos(\vartheta_3)}}
 \end{array}$$

$r_{23\perp} = \frac{n_2 \cos(\vartheta_2) - n_3 \cos(\vartheta_3)}{n_2 \cos(\vartheta_2) + n_3 \cos(\vartheta_3)}$ (Snell's Law)

$$\boxed{t_{23\Rightarrow} = \frac{2n_2 \cos(\vartheta_2)}{n_3 \cos(\vartheta_2) + n_2 \cos(\vartheta_3)} \quad \text{Snell's Law}}$$

$$\boxed{t_{23\perp} = \frac{2n_2 \cos(\vartheta_2)}{n_2 \cos(\vartheta_2) + n_3 \cos(\vartheta_3)}}$$

Three-layers Reflection



Product



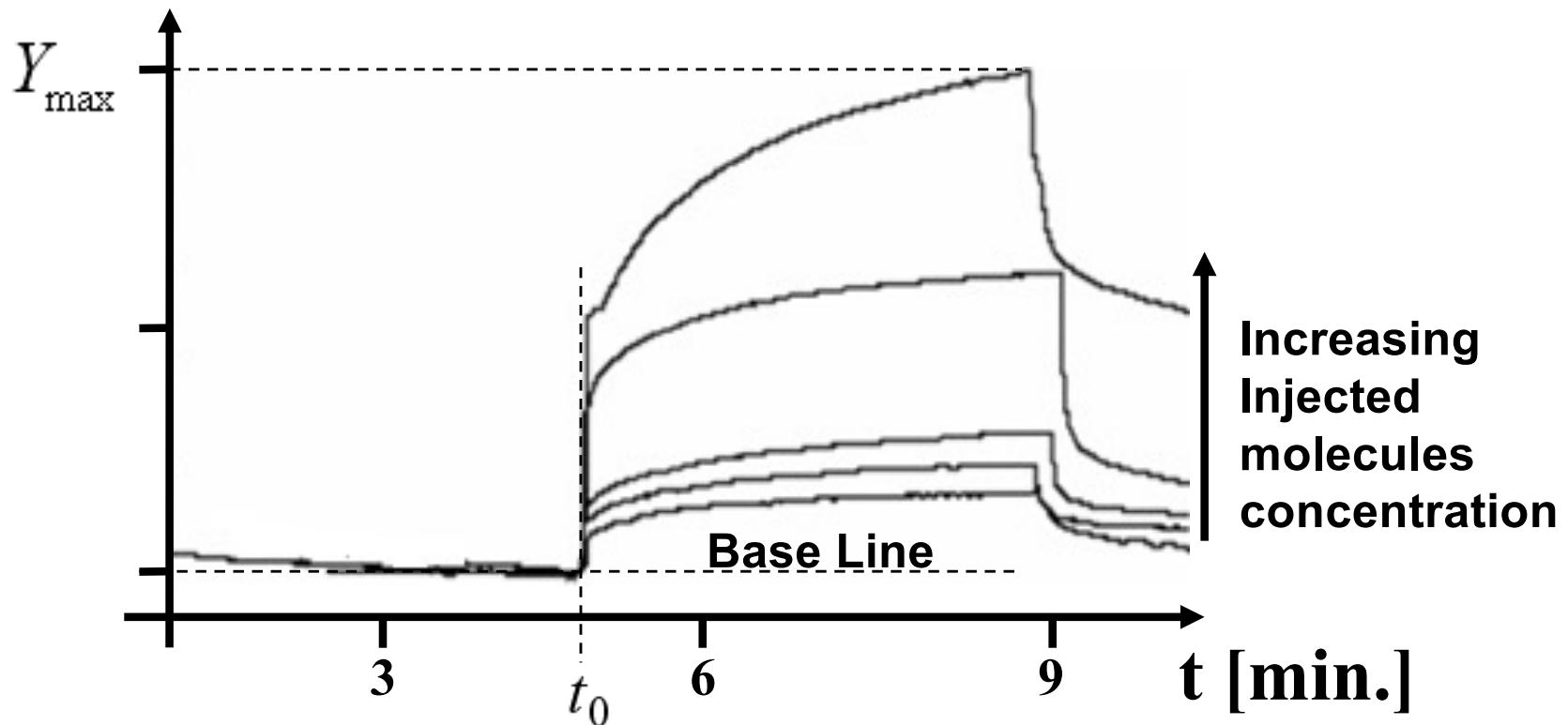
IAsys plus Affinity Sensor

(c) S.Carrara

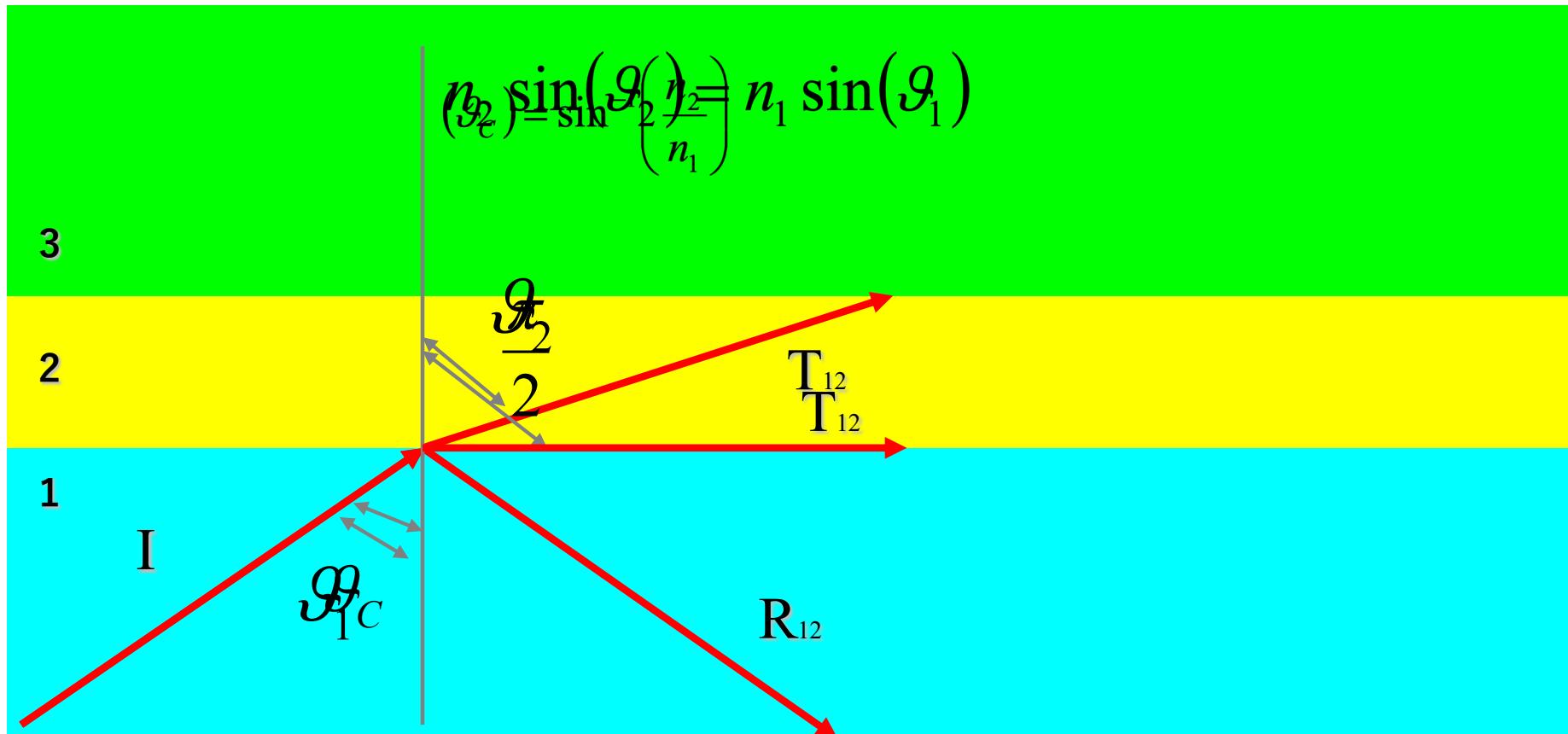
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Yield Monitoring

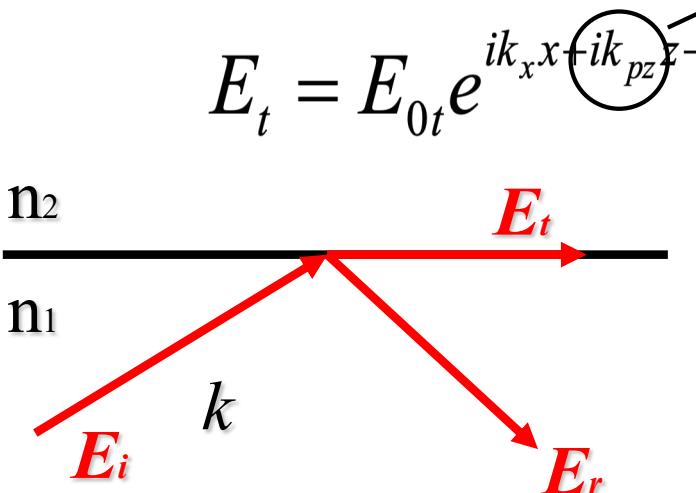
Yield = Percentage of covered surface



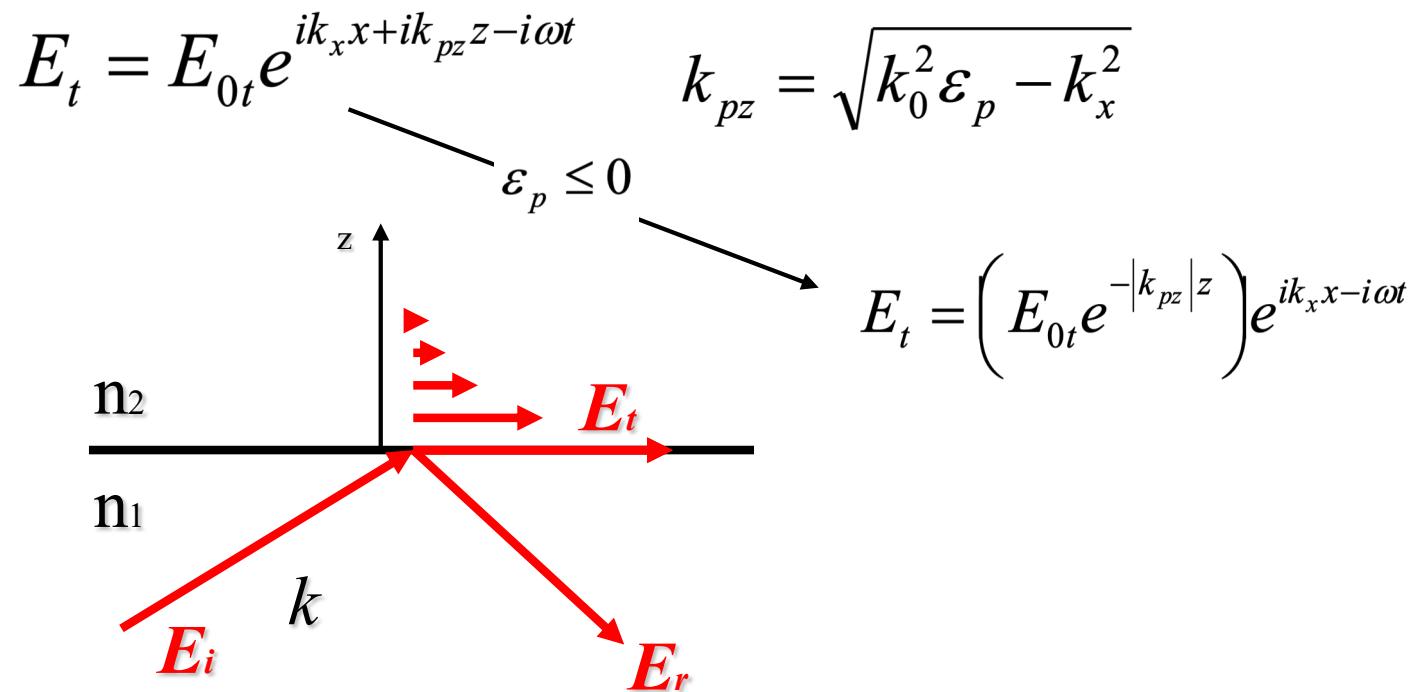
Three-layers Reflection



The Propagation along the interface

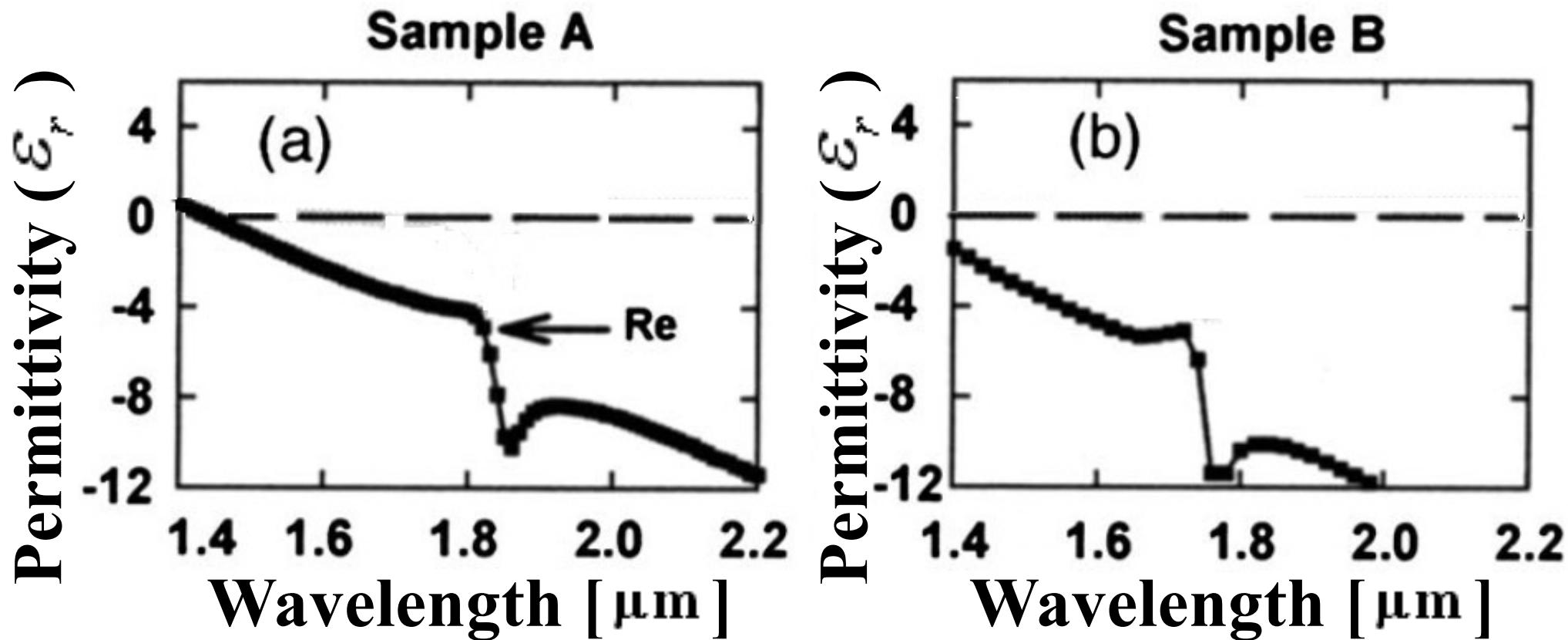
$$E_t = E_{0t} e^{ik_x x + ik_{pz} z - i\omega t}$$

$$k_{pz} = \sqrt{k_0^2 \epsilon_p - k_x^2}$$
$$\begin{cases} k_0 = \omega / c = 2\pi / \lambda \\ k_x = k_0 \sqrt{\epsilon_p} \sin(\vartheta) \\ n_2 = \sqrt{\epsilon_p \mu_p} \end{cases}$$
$$E_i = E_{0i} e^{ik_x x + ik_z z - i\omega t}$$
$$E_r = E_{0r} e^{ik_x x - ik_z z - i\omega t}$$

The Evanescent wave

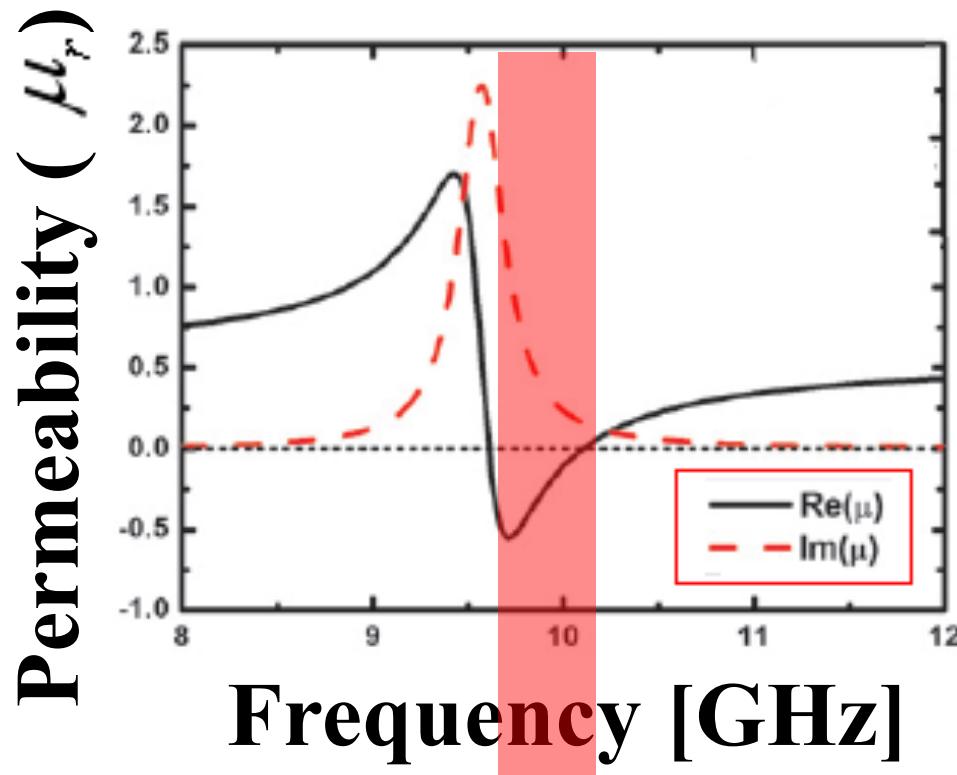


Negative Permeability of metals

Zhang *et al.* J. Opt. Soc. Am. B/Vol. 23, No. 3/March 2006 pag 434

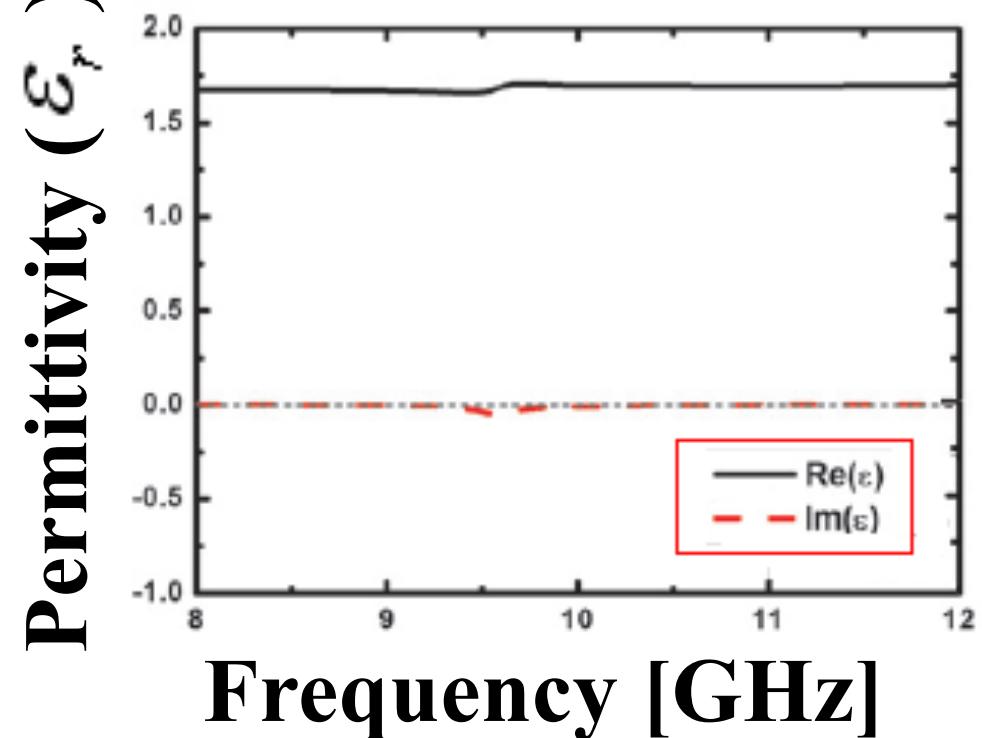


Negative Permittivity in metallic clots



Region of frequencies
with negative permeability

New Journal of Physics 10 (2008) 115039 (15pp)

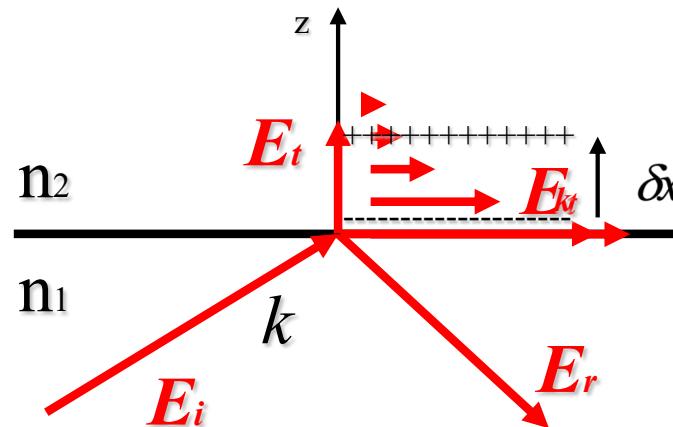


Negative dielectric constant

$$E_t = \left(E_{0t} e^{-|k_{pz}|z} \right) e^{ik_x x - i\omega t}$$

$$\epsilon_p \leq 0$$

!



$$F = ma = m \frac{\partial^2 \delta x}{\partial t^2}$$

$$F = eE_t = -eE_{\delta x} = -e \frac{\sigma}{\epsilon_0}$$

$$F = -e \frac{en_e \delta x}{\epsilon_0}$$

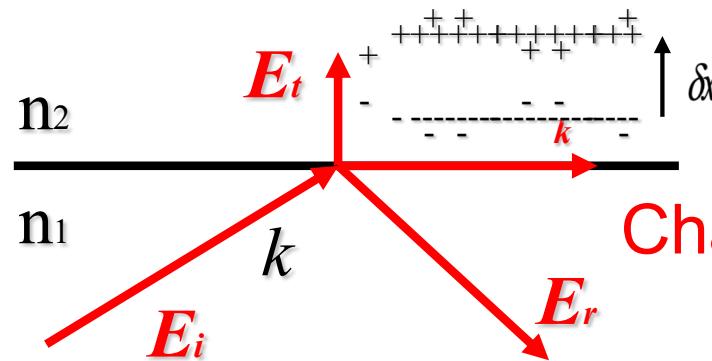
$$\frac{\partial^2 \delta x}{\partial t^2} + \frac{e^2 n_e \delta x}{m \epsilon_0} = 0$$

$$\omega_p^2 = \frac{e^2 n_e}{m \epsilon_0} \quad \frac{\partial^2 \phi}{\partial t^2} - \frac{e^2 n_e}{m \epsilon_0} \phi = 0$$

Electronic Waves

$$\frac{\partial^2 \delta x}{\partial t^2} + \omega_p^2 \delta x = 0 \longrightarrow \delta x = \delta x_0 e^{-i\omega_p t} = \frac{\epsilon_0 E_{0t} e^{-|k_{pz}|z_p}}{e} e^{-i\omega_p t}$$

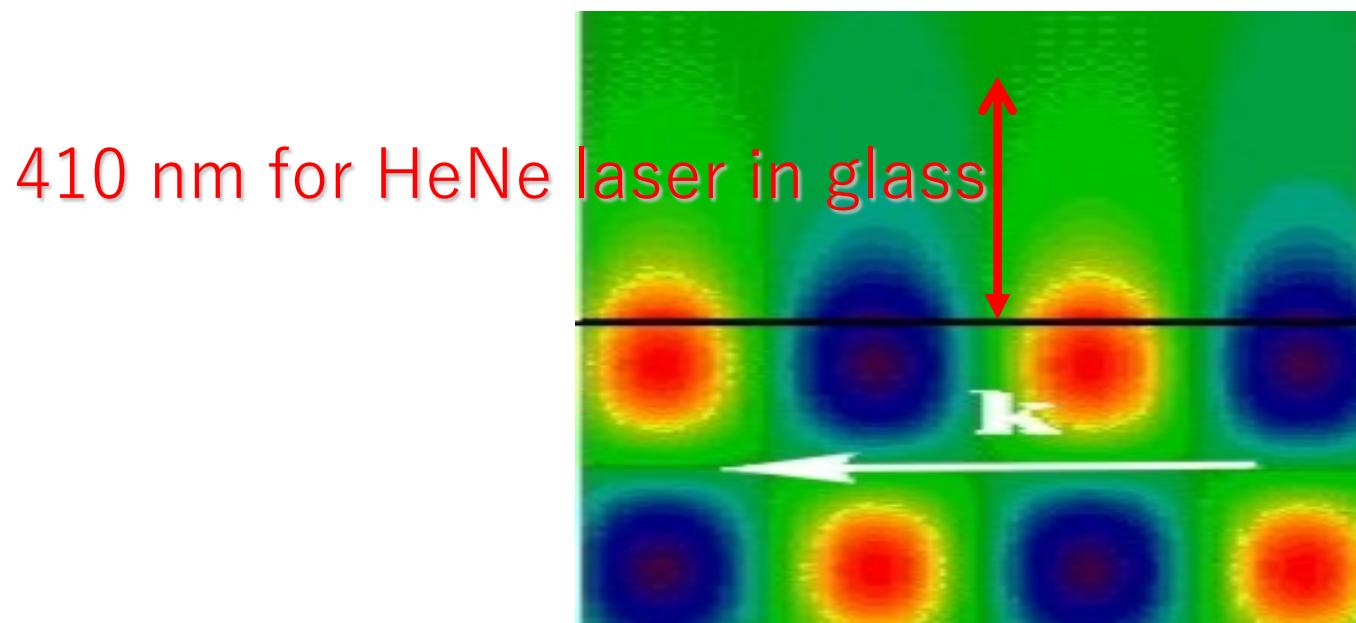
The Plasmon!



Characteristic of the evanescent wave

$$\omega_p^2 = \frac{e^2 n_e}{m \epsilon_0}$$
$$k_{pz} = \sqrt{k_0^2 \epsilon_p - k_x^2}$$

Simulation of Evanescent wave propagation



Penetration of the Evanescent Wave

For an amplitude of 1/3 of the value in $z=0$, we have

$$E_{ot}e^{-|k_{mz}|z} = \frac{1}{3}E_t|_{z=0} = \frac{1}{3}E_{0t} \rightarrow e^{-|k_{mz}|z} = \frac{1}{3} \approx \frac{1}{e}$$

By extracting z :

$$z = \frac{1}{|k_{mz}|} = \frac{c_0}{2\pi f \sqrt{|\mu_r \epsilon_r|}} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}}$$

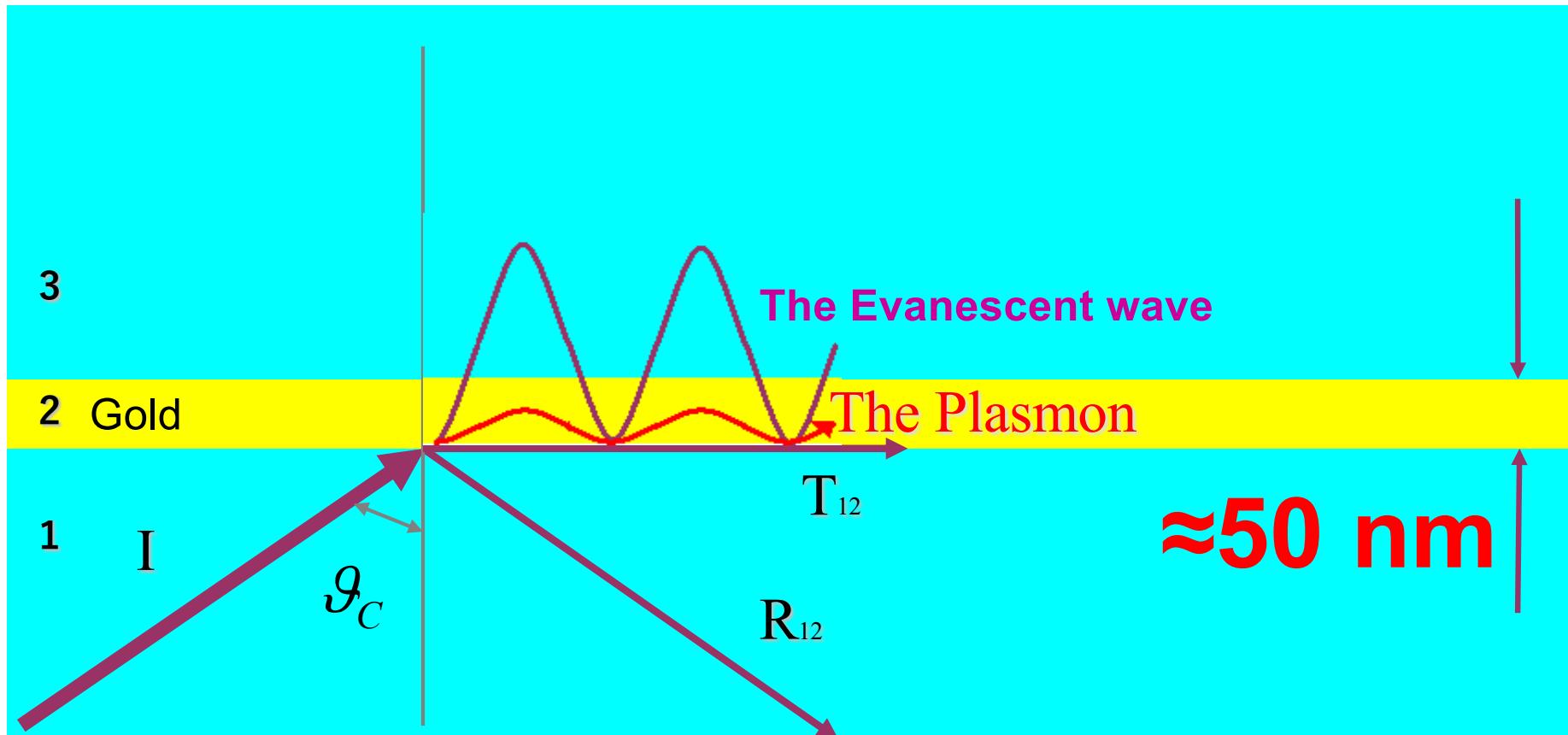
For gold, with relative magnetic permeability close to one and relative electric permittivity equal to 6.9, we obtain a thickness of

$$z_{gold} = \frac{1}{|k_{mz}|} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}} = \frac{400 \text{ nm}}{\sqrt{6.9 \cdot 1}} \approx 152 \text{ nm}$$

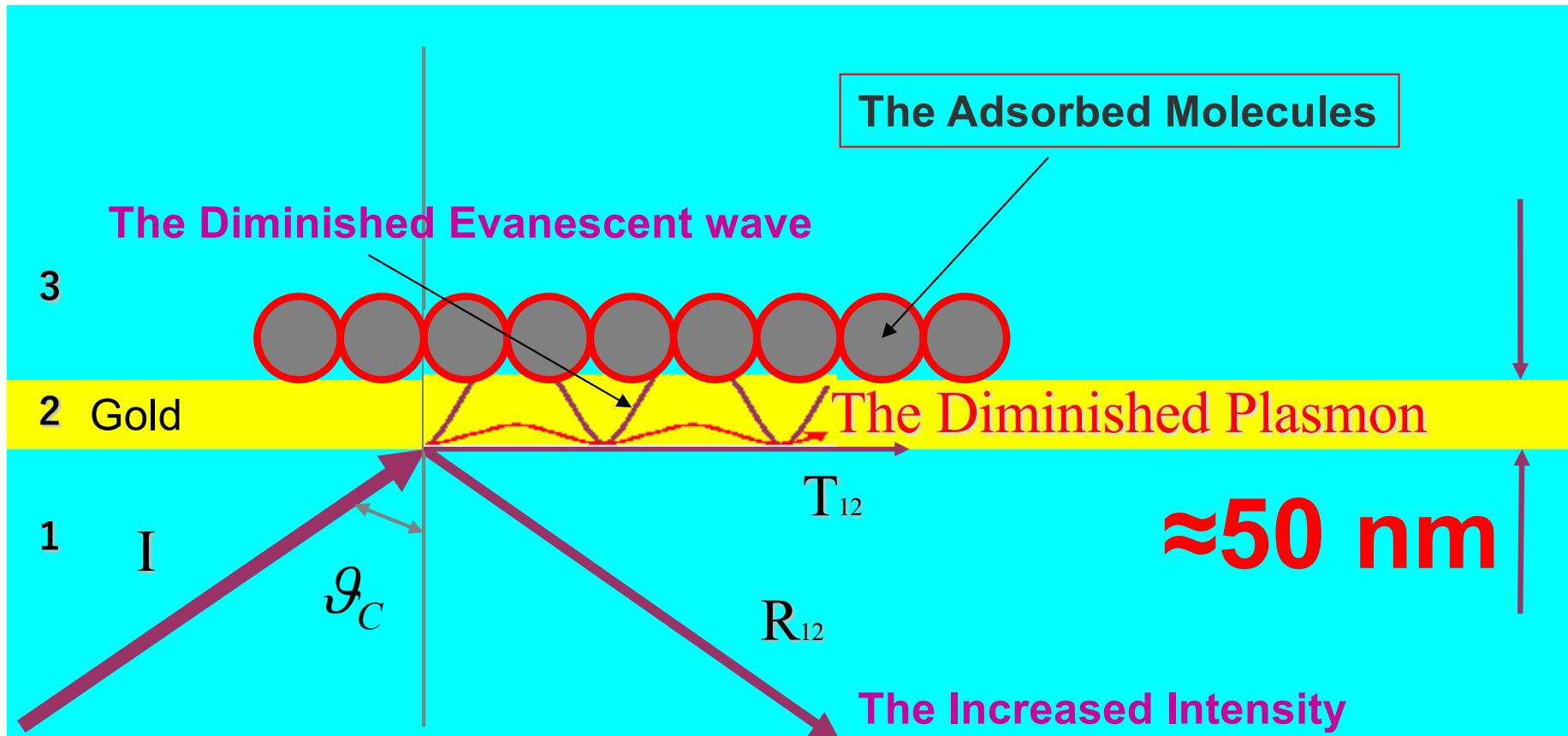
For nickel, with permeability and permittivity equal to 100 and 10 (respectively), we get:

$$z_{nickel} = \frac{1}{|k_{mz}|} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}} \approx \frac{400 \text{ nm}}{\sqrt{100 \cdot 10}} \approx 12 \text{ nm}$$

Penetration of the Evanescent Wave



Perturbation of the Evanescent Wave

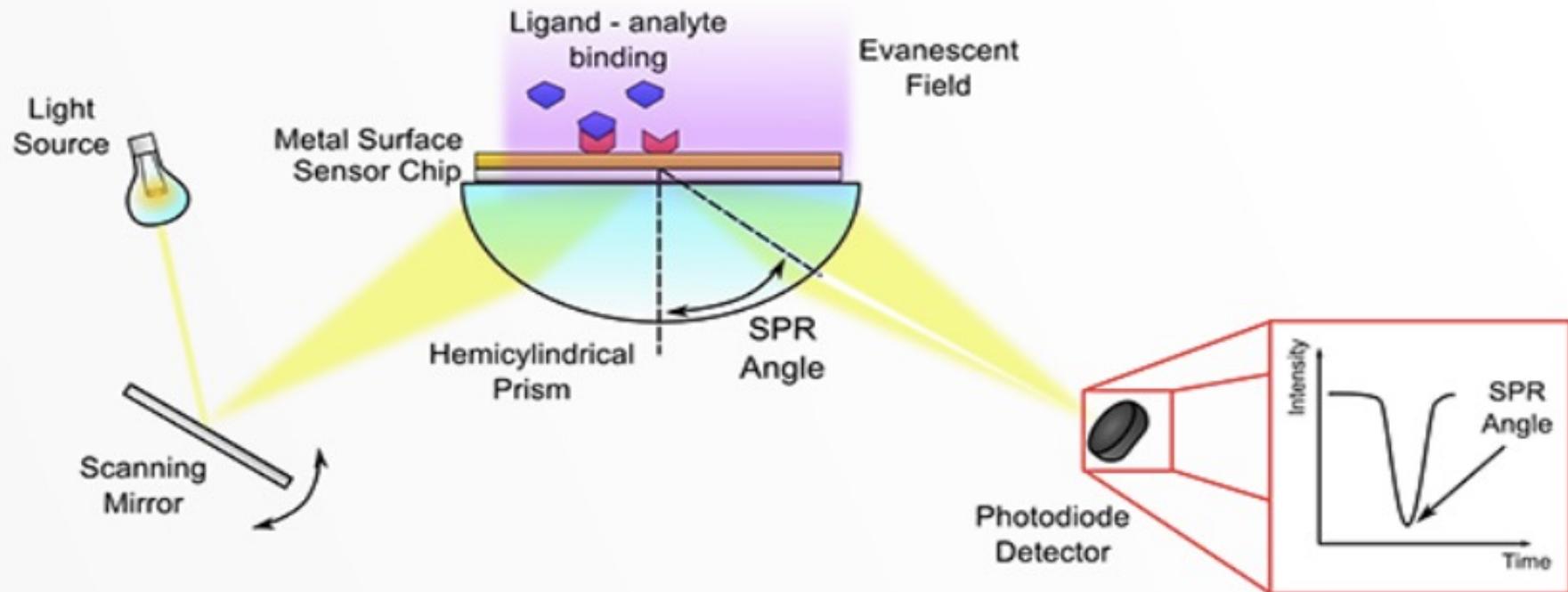


A Plasmon Resonance based Biosensor



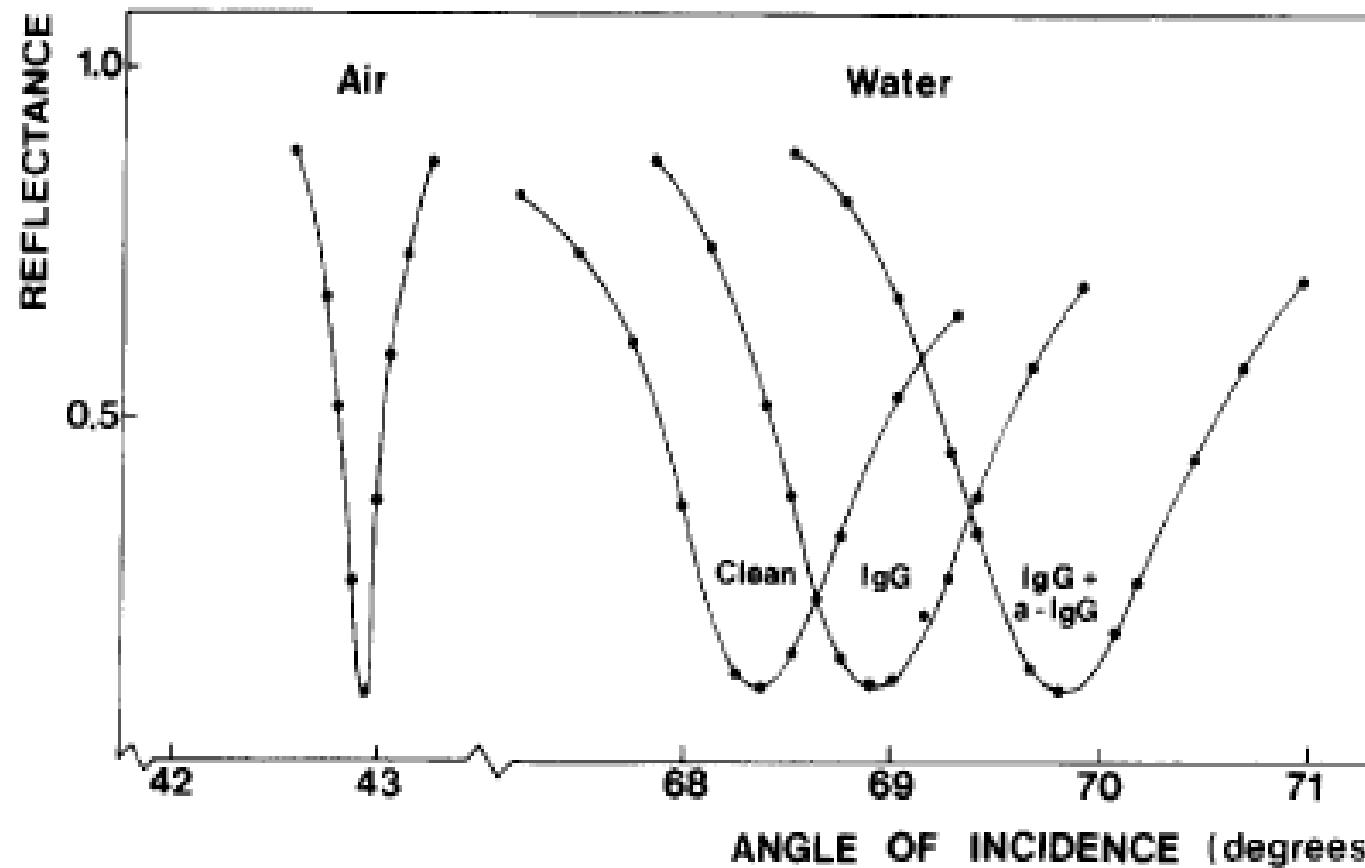
BIACORE 3000

Working Principle



The presence of the complexes onto the gold surface will change the angle of resonance for the formation of the Surface Plasmon.

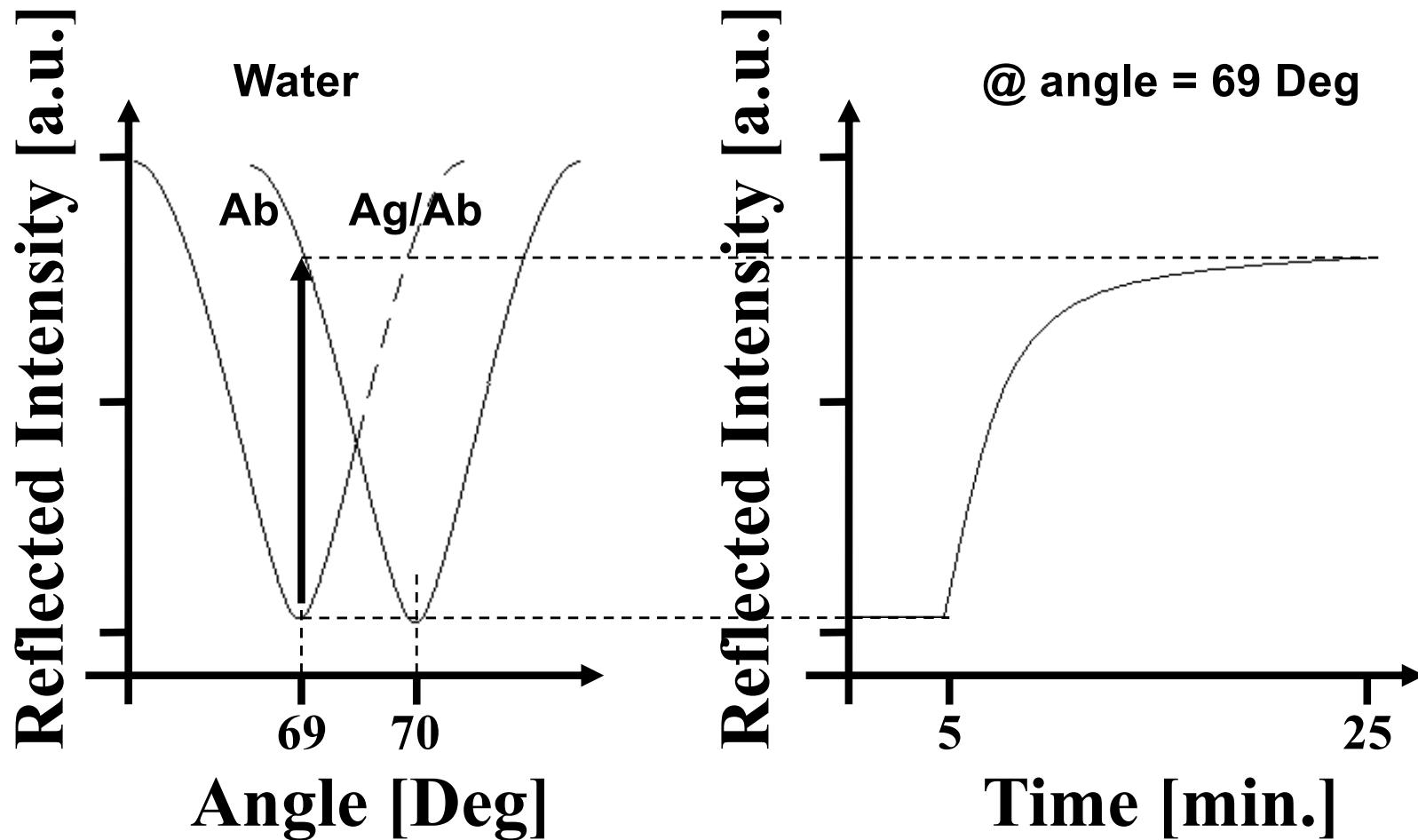
Characterization of Monoclonal antibodies



Bo Liedberg, et al, Biosensors & Bioelectronics 10 (1995) i-iv

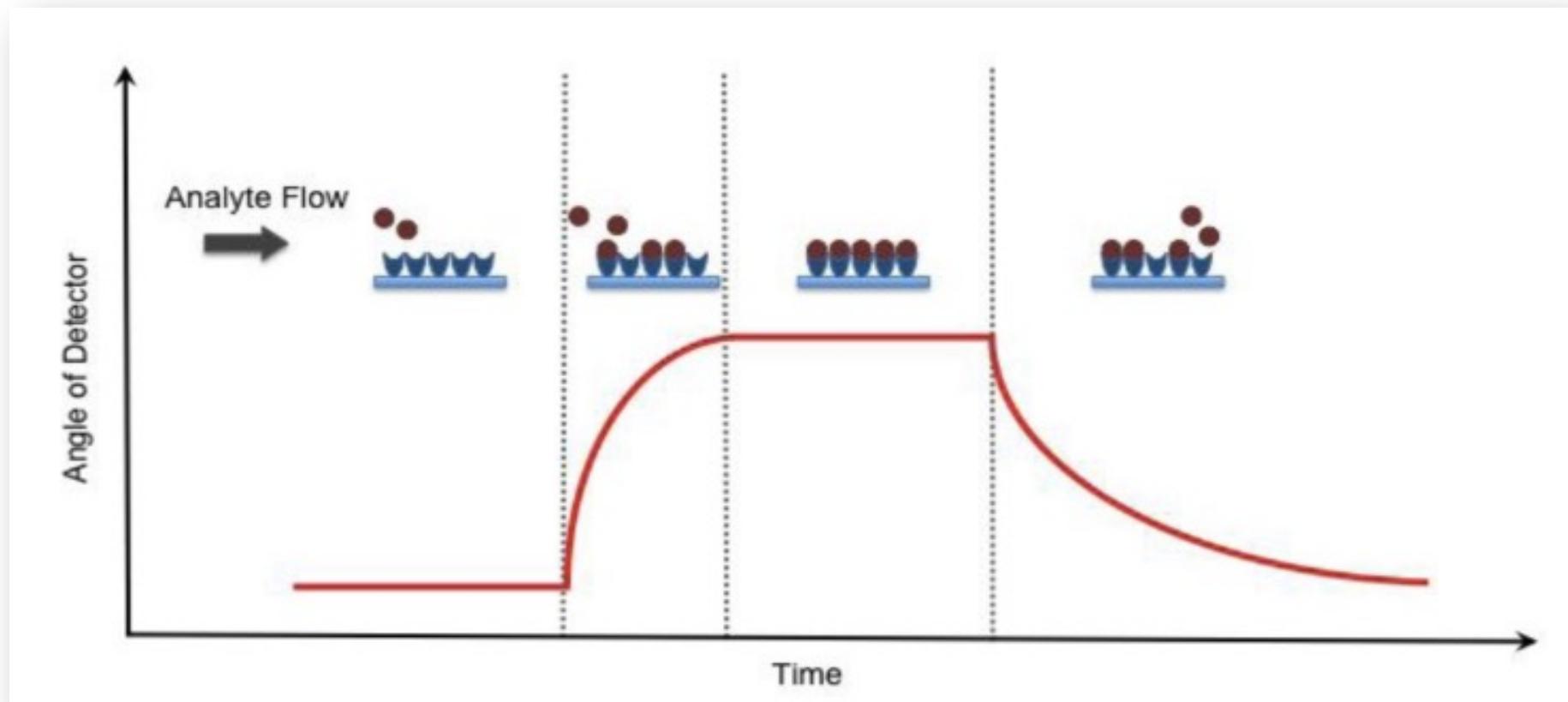
Shift in the resonant angle to sense IgG adsorption

Kinetic Studies



The kinetics could be reached by means of the change of the reflected intensity at fixed angle

Detection of Binding Events



Molecular uptake as monitored by SPR

SPR on SAM

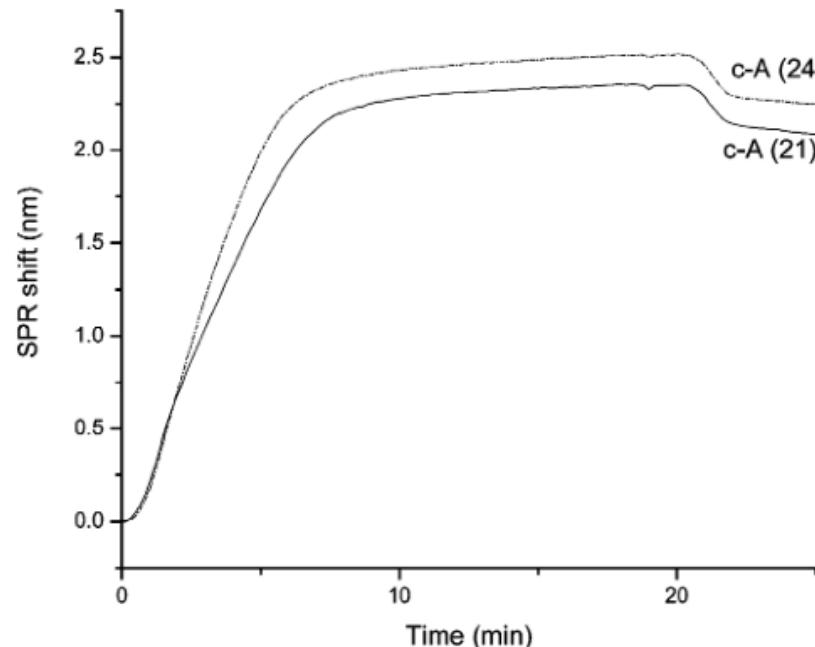


Figure 7. Comparison of the hybridization of a truncated complement (c-A 21) with the hybridization of the full-length complement (c-A 24). The ssDNA/OEG surface was prepared from a solution with a DNA mole fraction of 0.02.

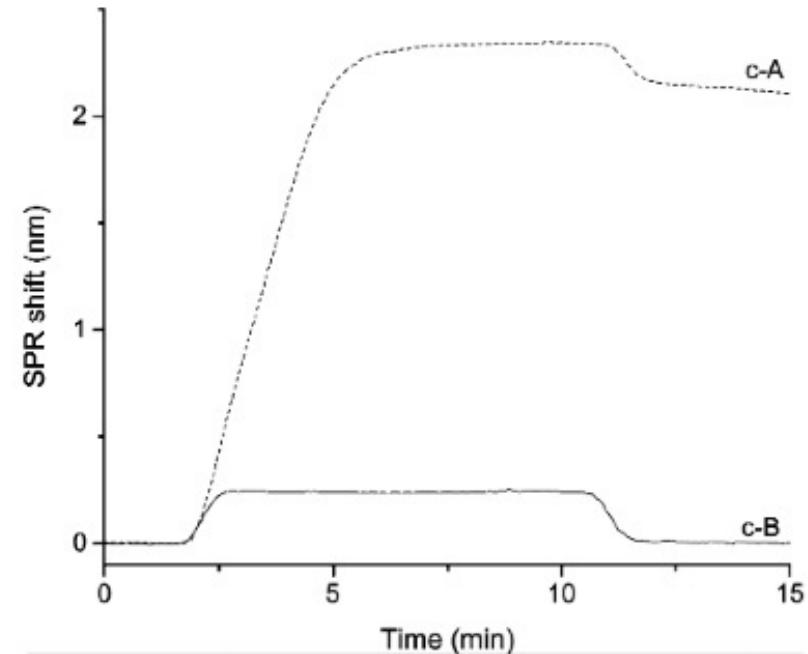


Figure 2. Control experiment to test DNA specificity. Both c-A and c-B were flowed over a sequence A ssDNA/OEG SAM, but only the complementary DNA hybridized. The ssDNA/OEG surface was prepared from a solution with a DNA mole fraction of 0.02.

Langmuir, Vol. 22, No. 10, 2006

DNA hybridization as monitored by SPR

How to characterize the Probes Immobilization?

We have seen what are the mechanisms of self-assembly!

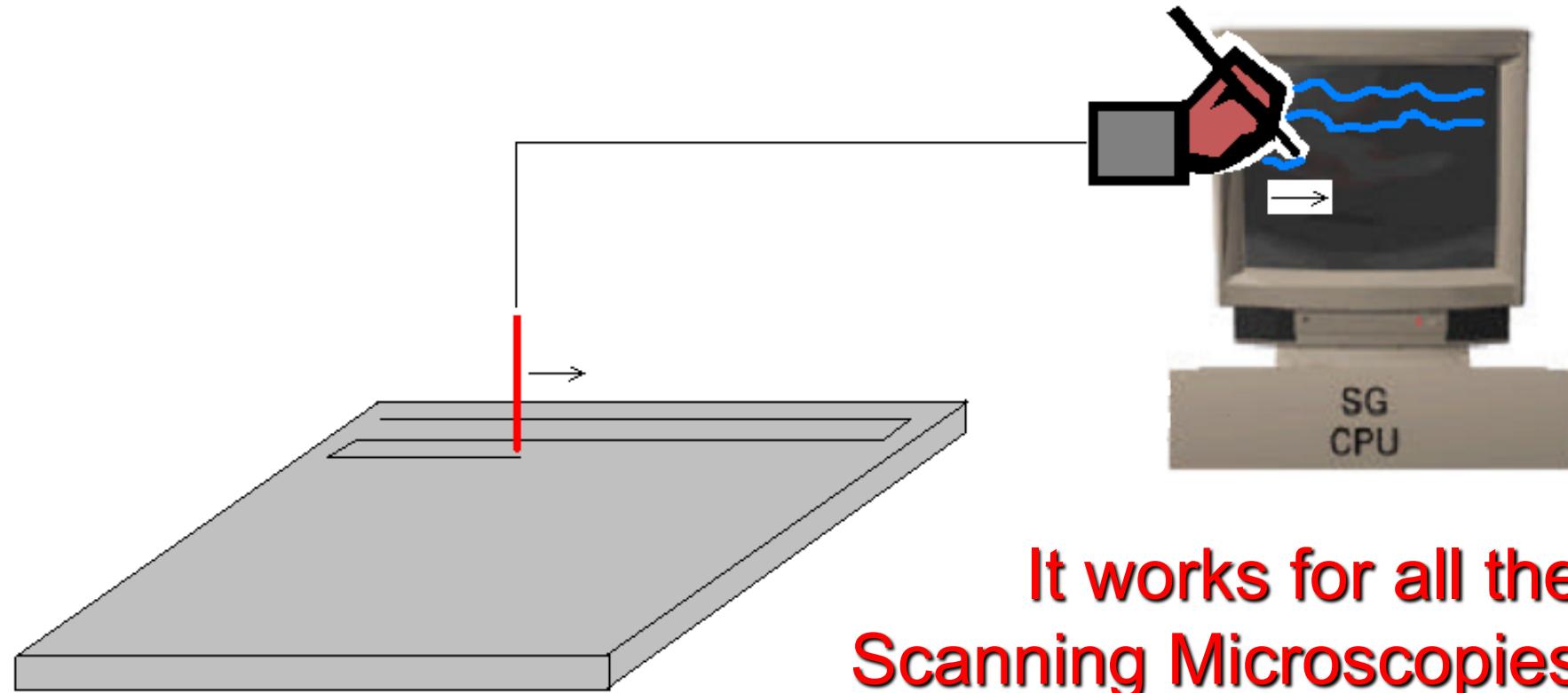
How to monitor the self-assembly process?

How to check the film quality?

Four different Microscopies

1. Transmission Electron Microscopy (TEM)
2. Scanning Electron Microscopy (SEM)
3. Atomic Force Microscopy (AFM)
4. Scanning Tunneling Microscopy (STM)

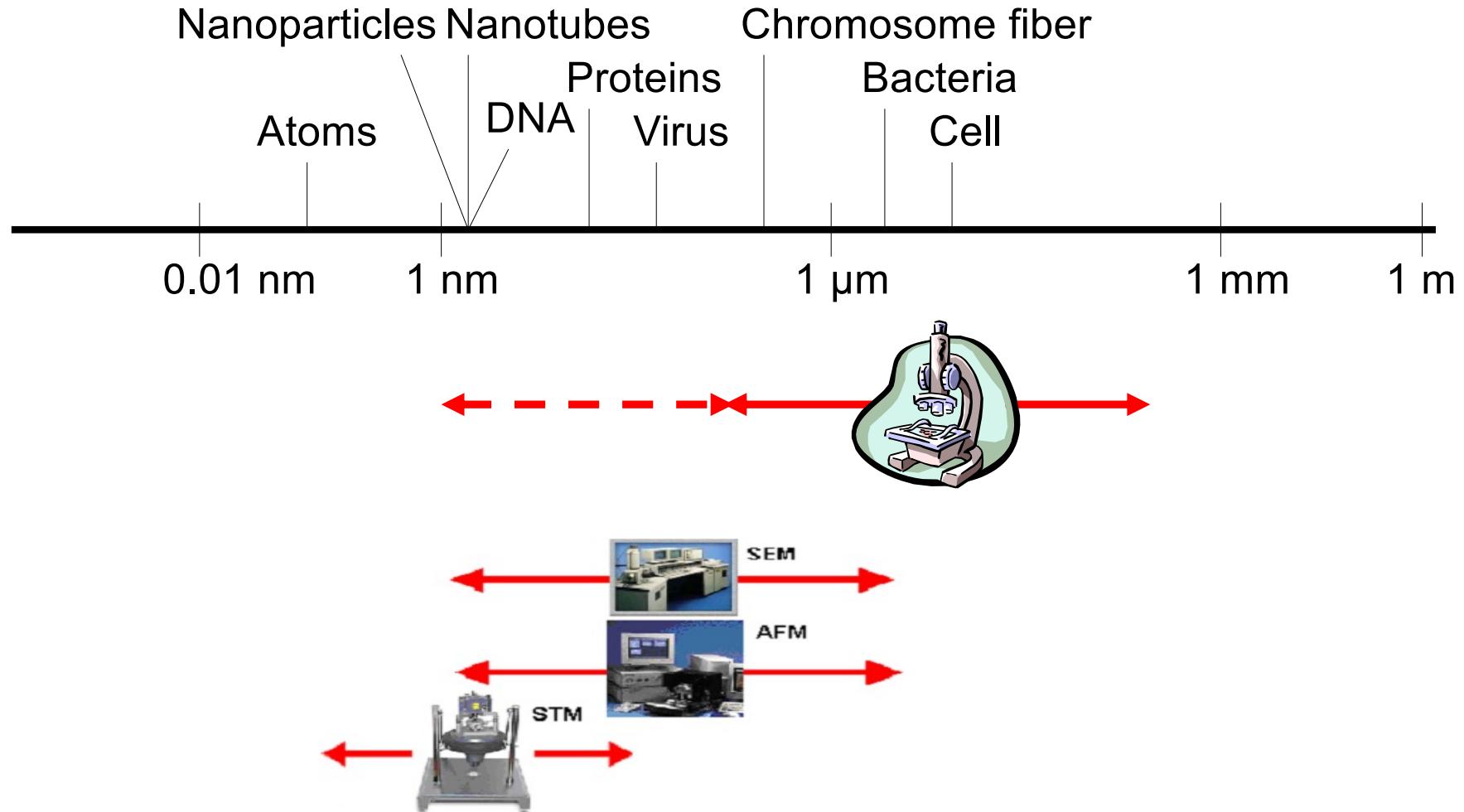
All are Scanning Microscopies



**It works for all the
Scanning Microscopies**

The sample scanning generates an image visualized with computer graphic tools

SEM Microscopy



Electron Microscopies

Scanning
Electron
Microscopy

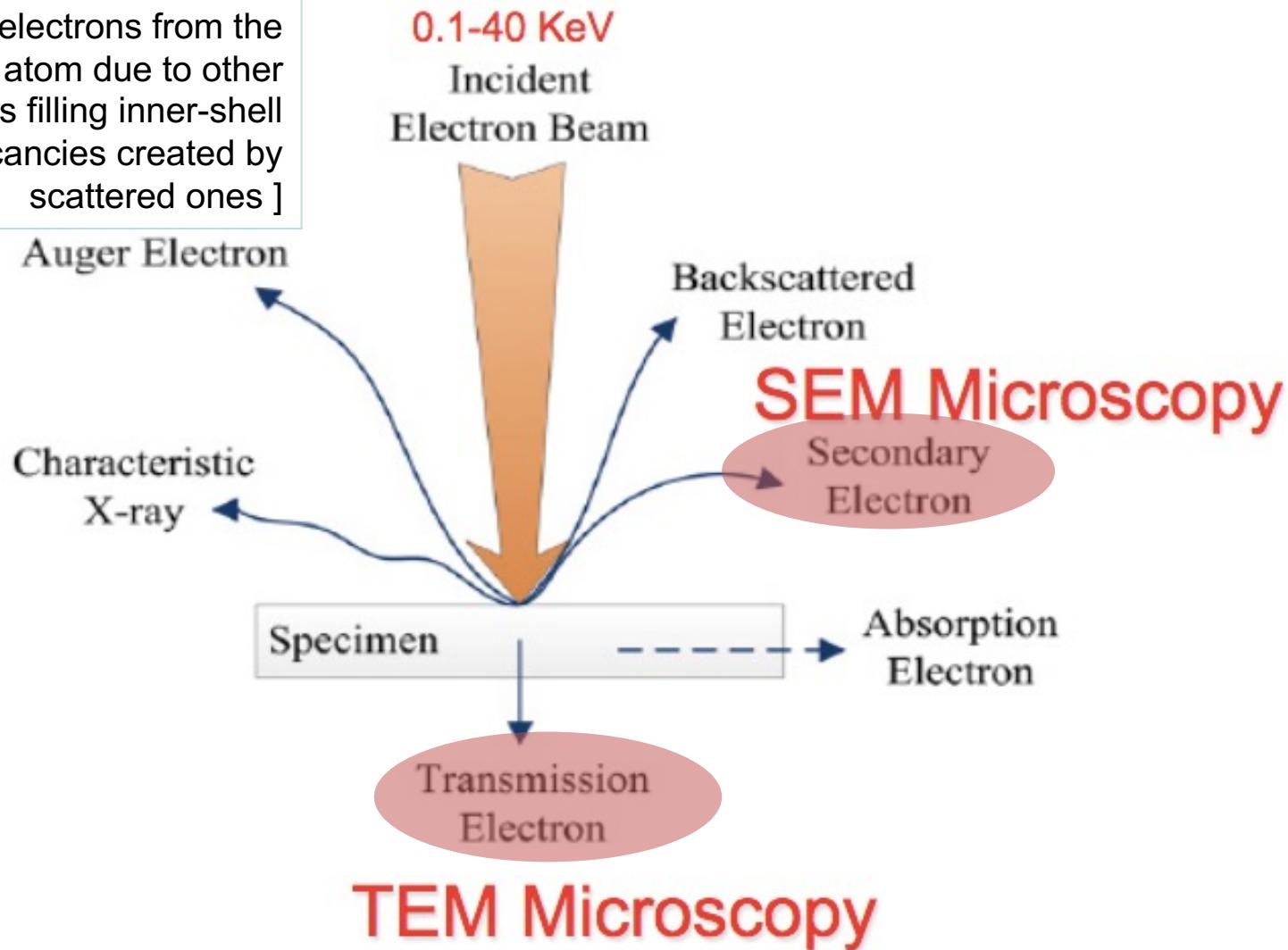


Transmission
Electron
Microscopy

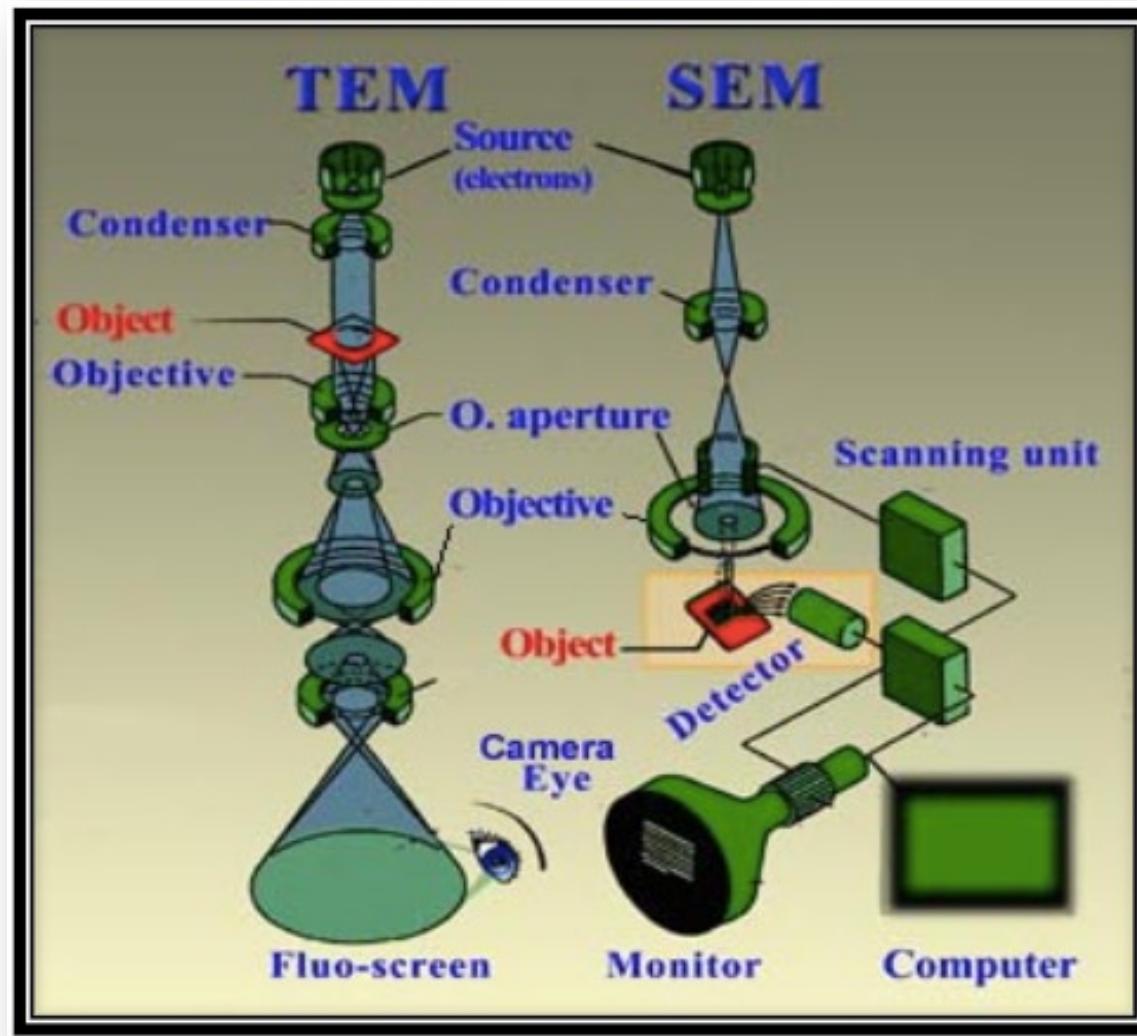


Electron Microscopy Principle

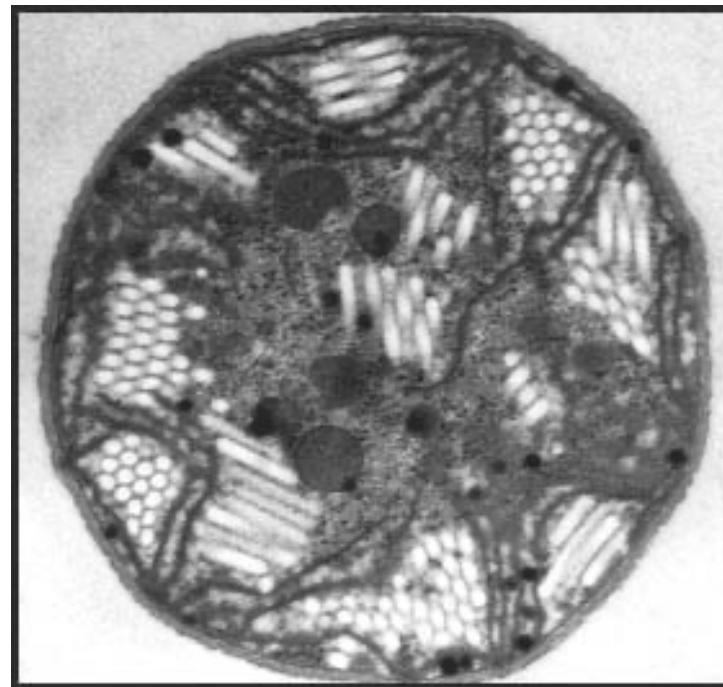
[Emitted electrons from the same atom due to other electrons filling inner-shell vacancies created by scattered ones]



Electron Microscopies

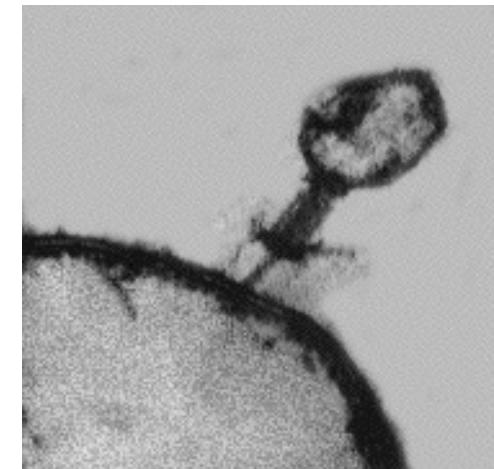
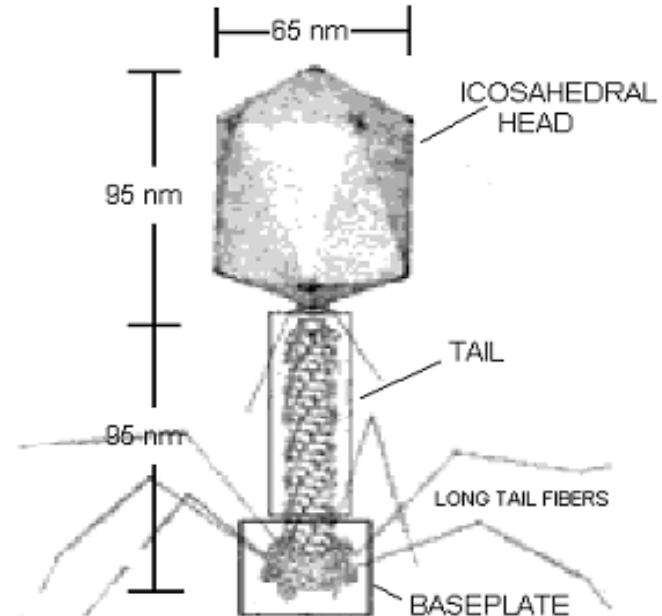


TEM Imaging



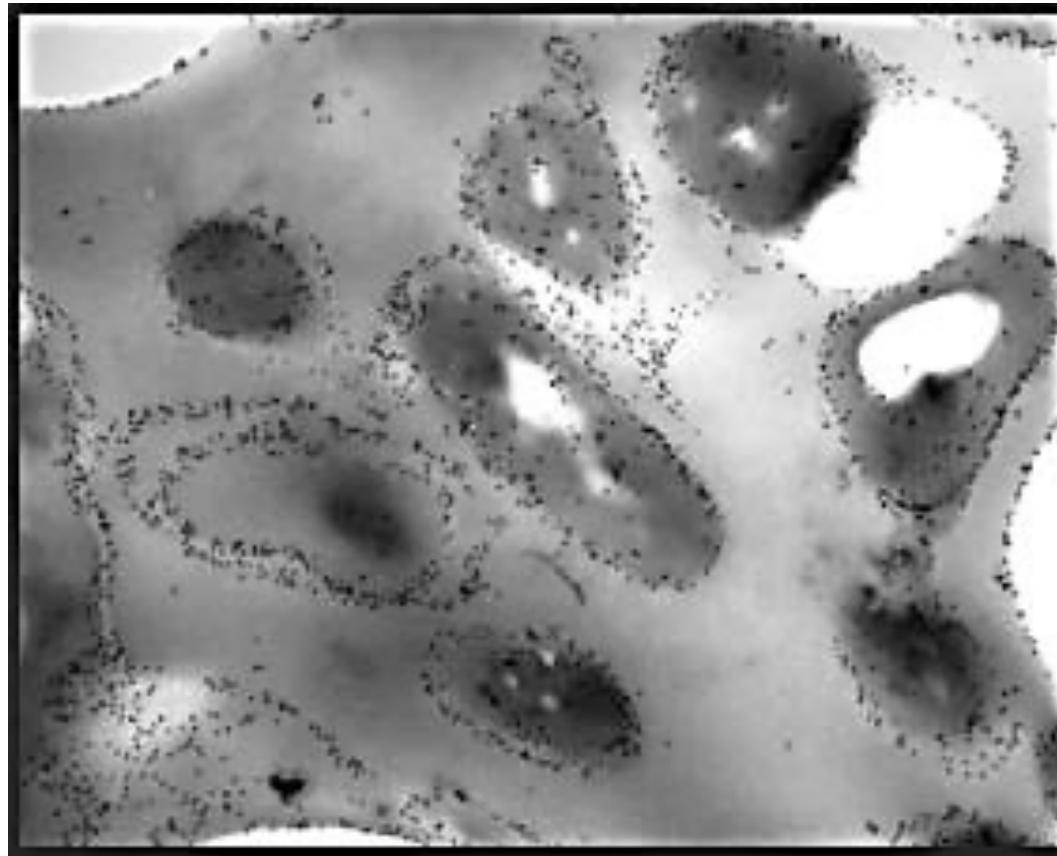
Cell of Cyanobacteria *Microcystis* by TEM

TEM Imaging



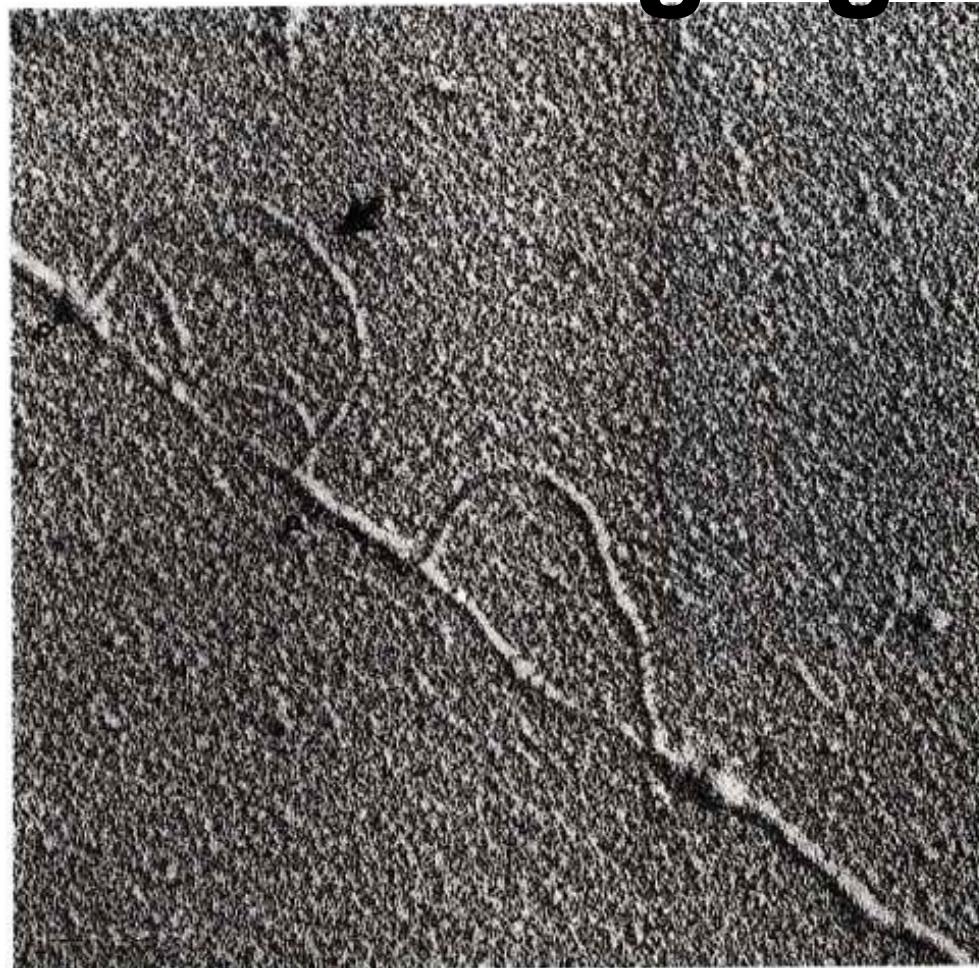
Virus T4 Bacteriophages

SEM Imaging



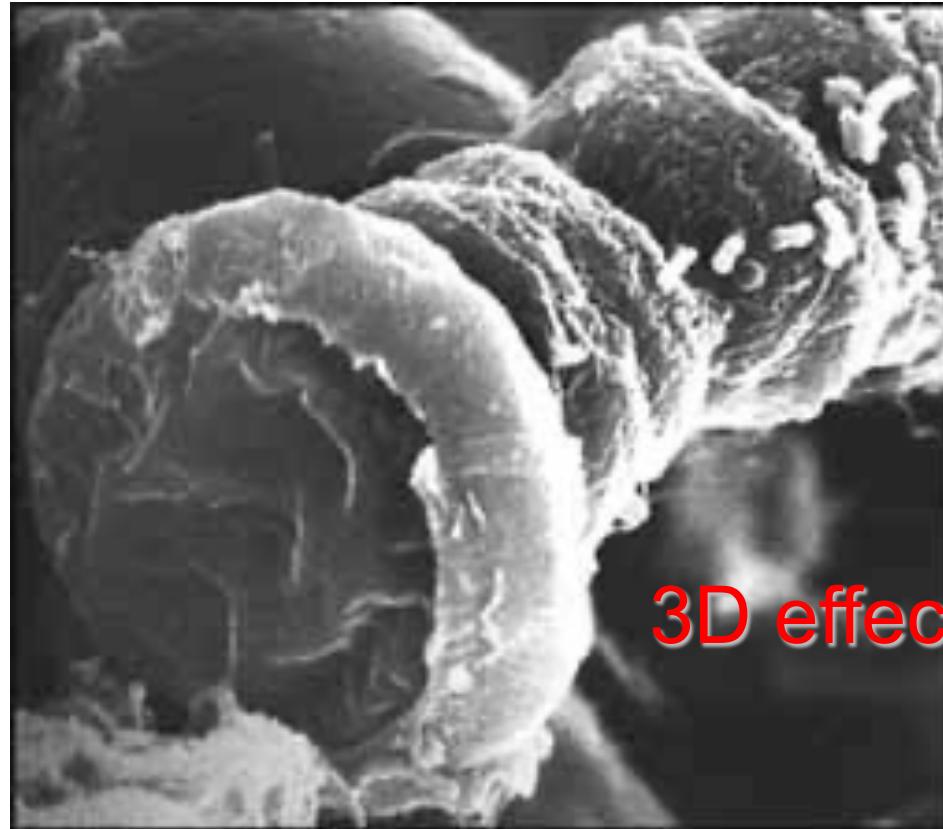
Antigens localized on the surface
of bacteria cells

SEM Imaging



Isolated Chromatin (DNA-macromolecules including hystons and not-histons proteins) of about 30 nm and with small filament

SEM Imaging

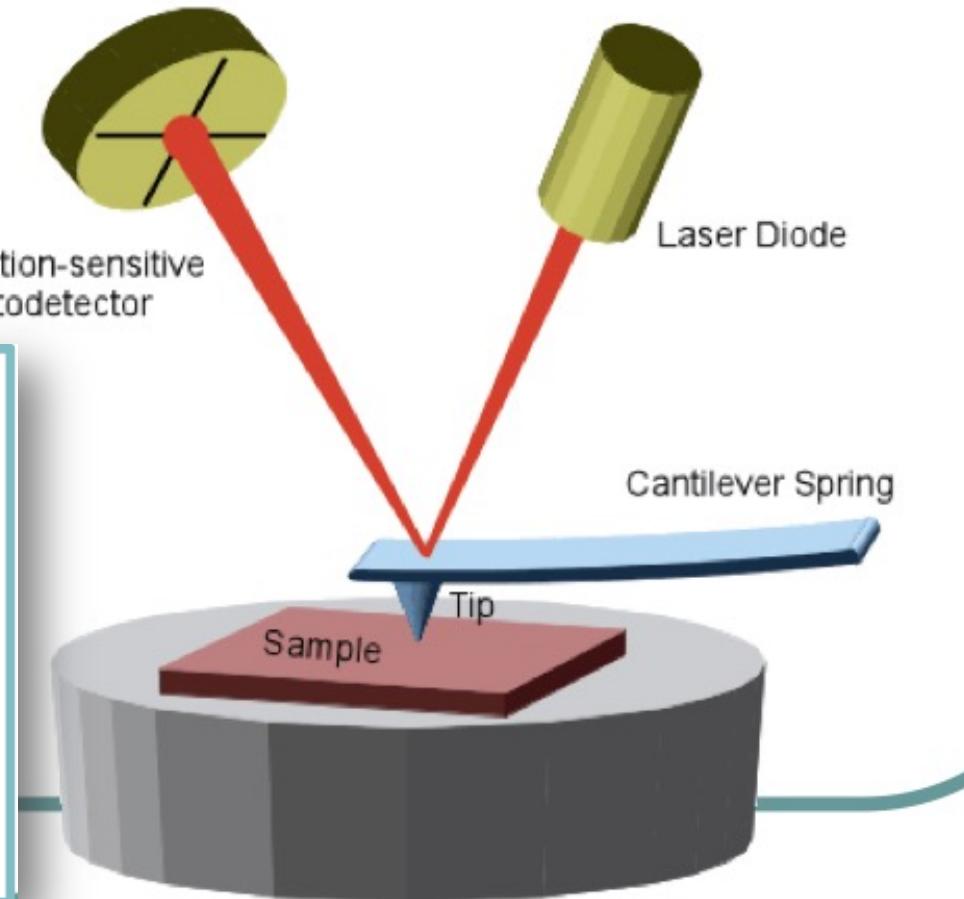


End part of *Nodularia*
(cyanobacteria in filament shape)

AFM detection principle

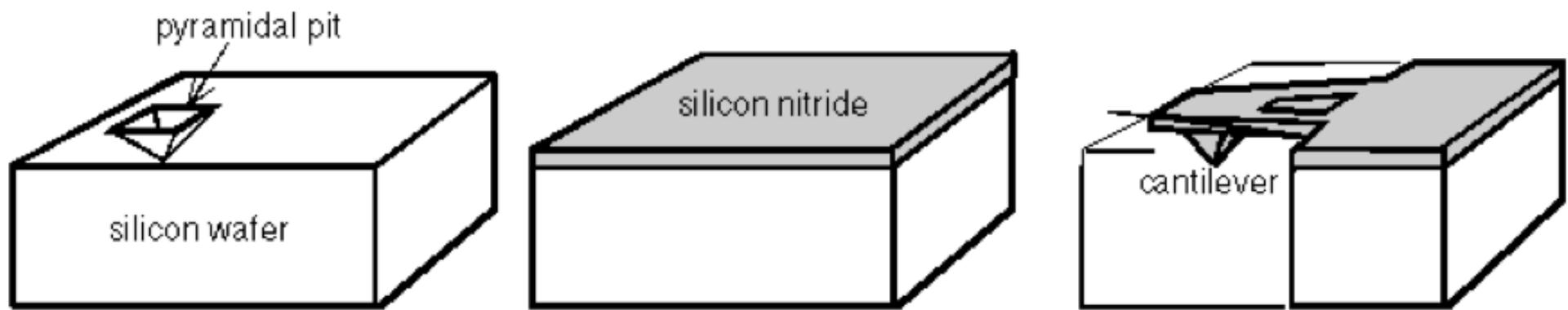
3 major abilities:

1. force measurement
between probe-sample
2. imaging from forces that
sample imposes on probe
(3D, pseudocolor)
3. manipulation use forces
to change sample
properties



Detection principle is obtained by monitoring the bending of the cantiliver that host the tip

AFM Tip fabrication



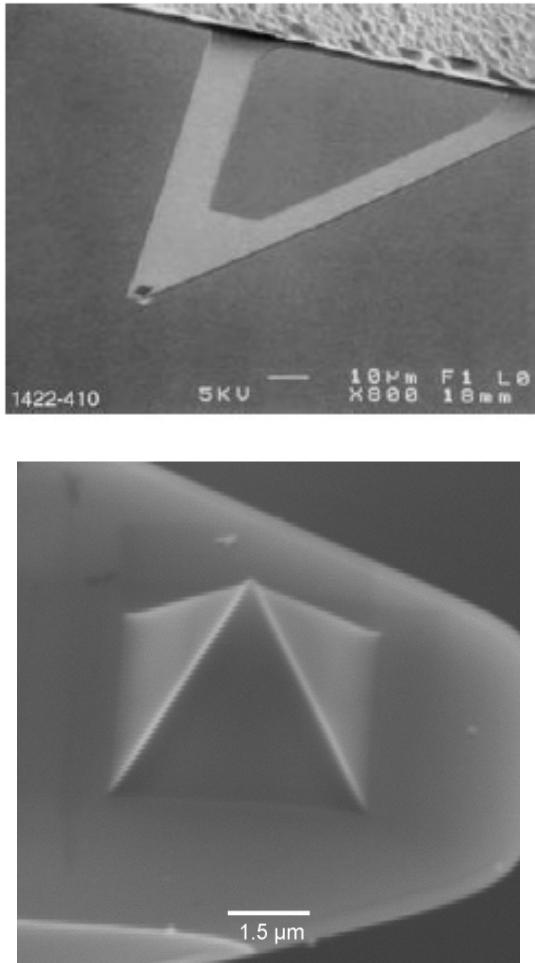
Pit etching in Si

Si₃N₄ coating

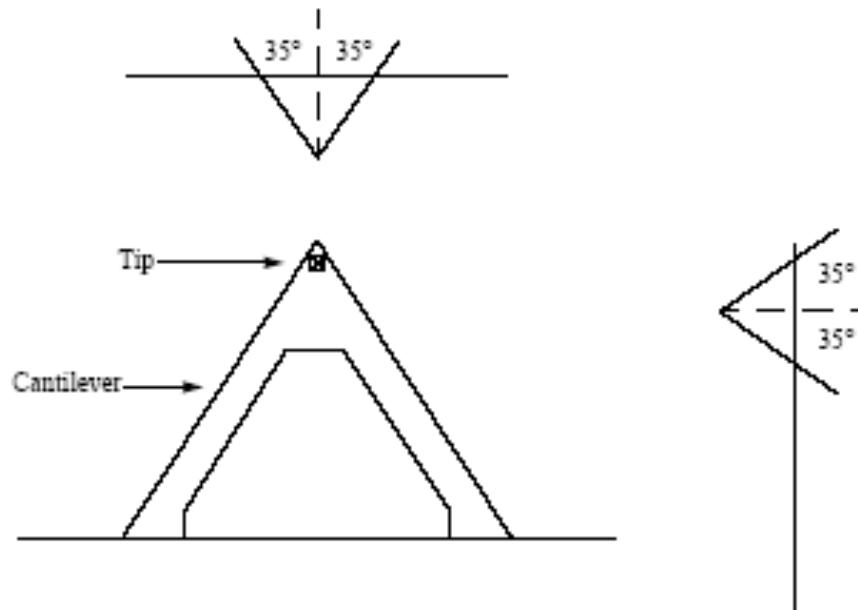
Si underetching

AFM tips are typically sculpted on silicon wafers

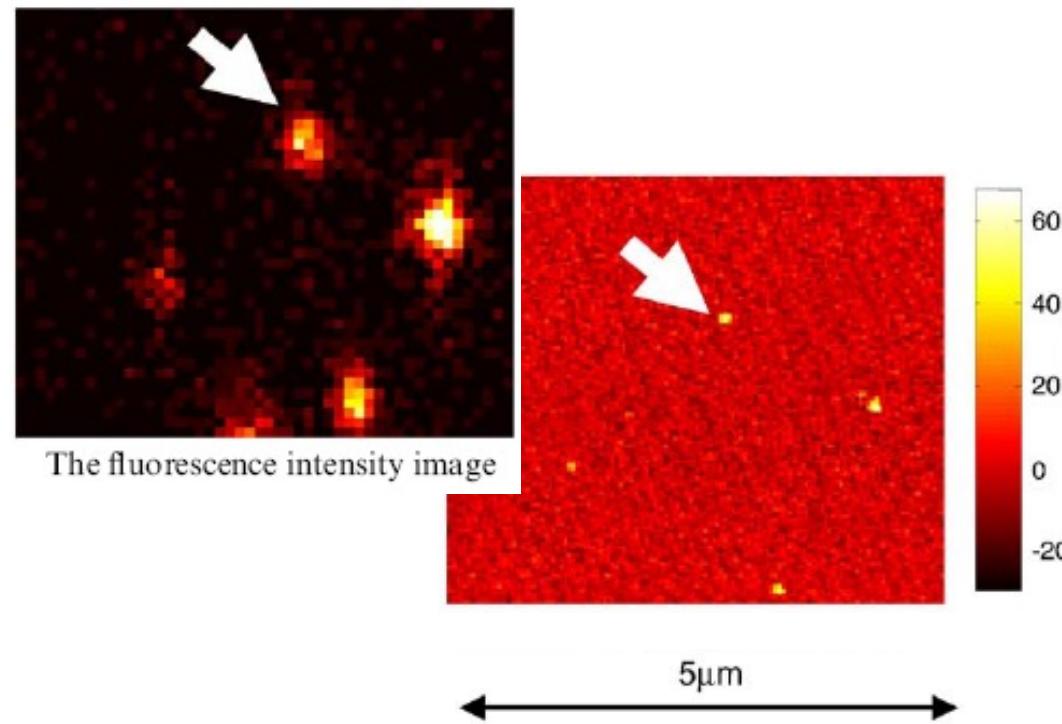
SEM on Silicon nitride probes



Tip Sidewall Angles of Silicon Nitride Probes

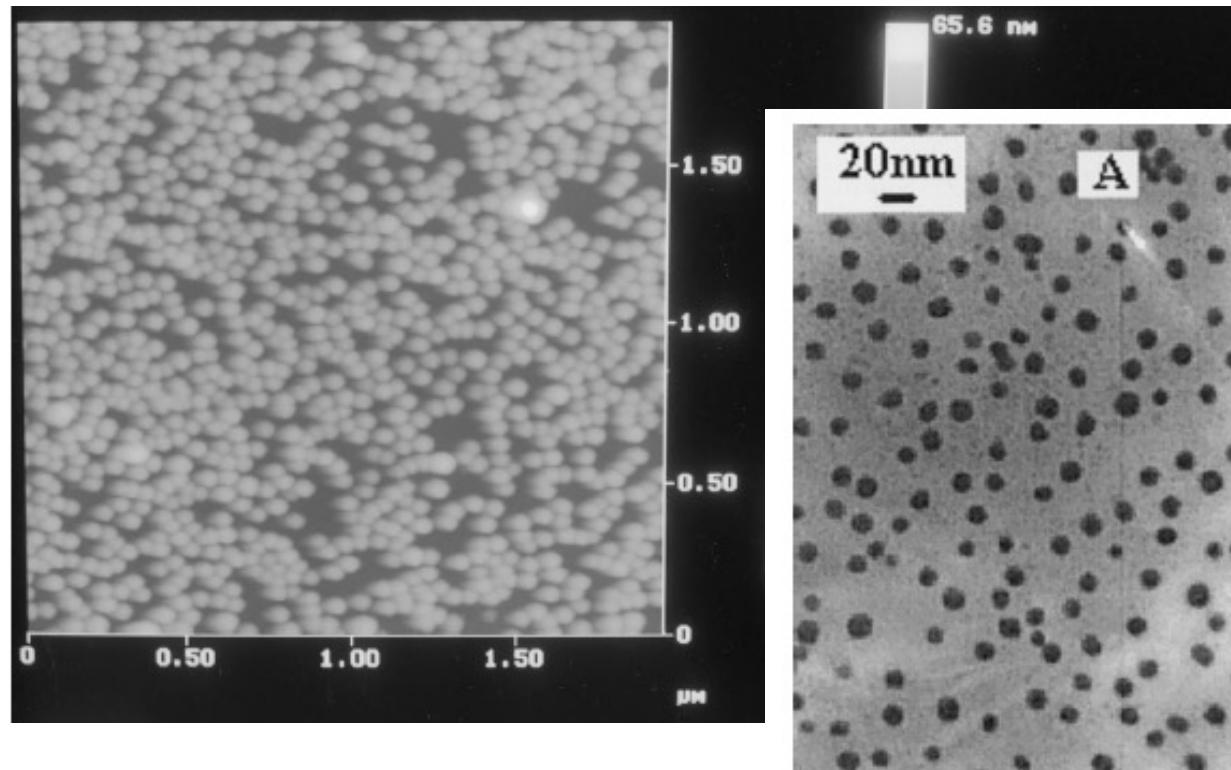


Optics versus AFM



Fluorescent Nanoparticles with average size of about 40 nm

AFM Imaging

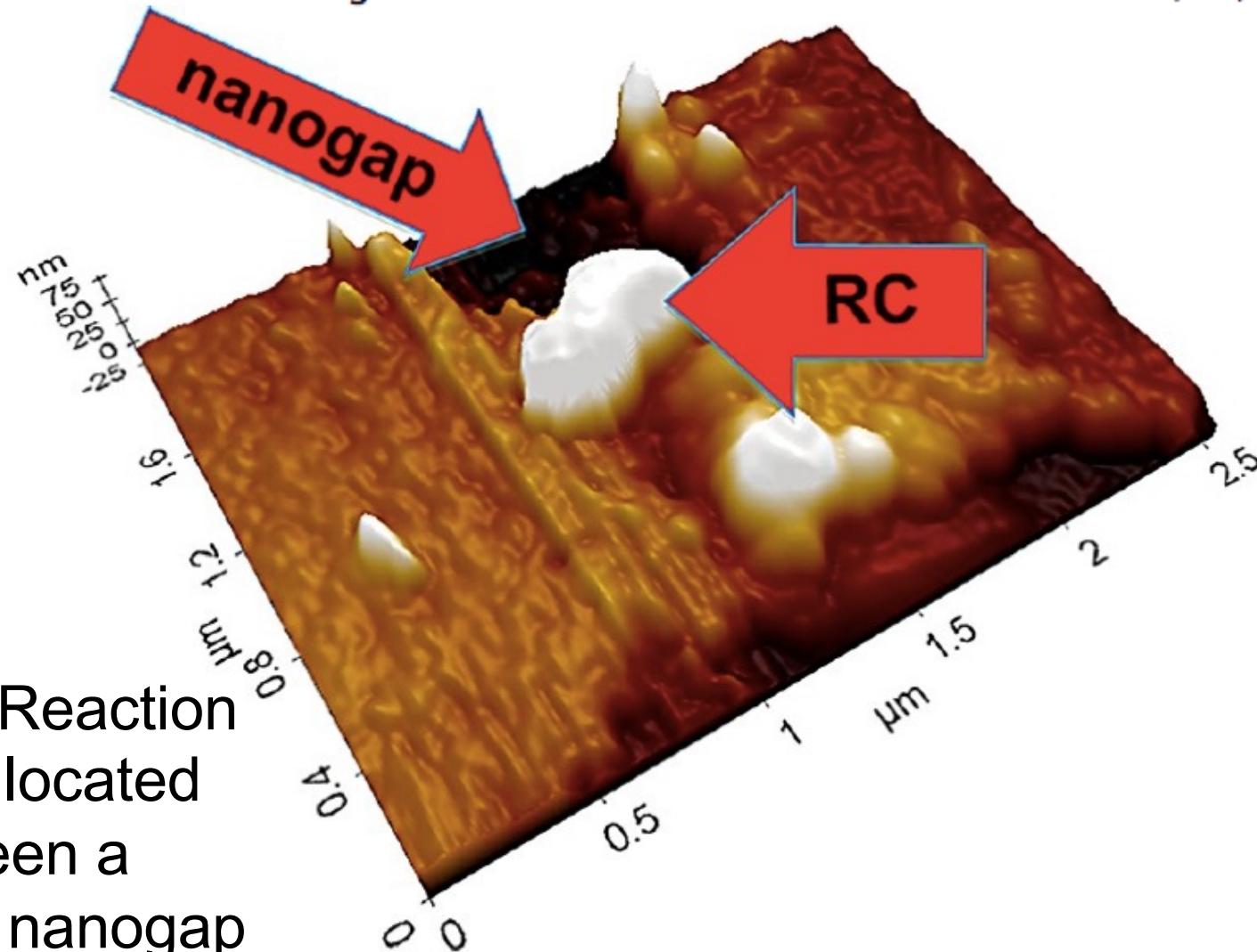


TEM images

Gold nanoparticles made off gold core and a thiols-shell to stabilize the particle

AFM Imaging in Air

[dx.doi.org/10.1021/bm301063m](https://doi.org/10.1021/bm301063m) | *Biomacromolecules* 2012, 13, 3503–3509

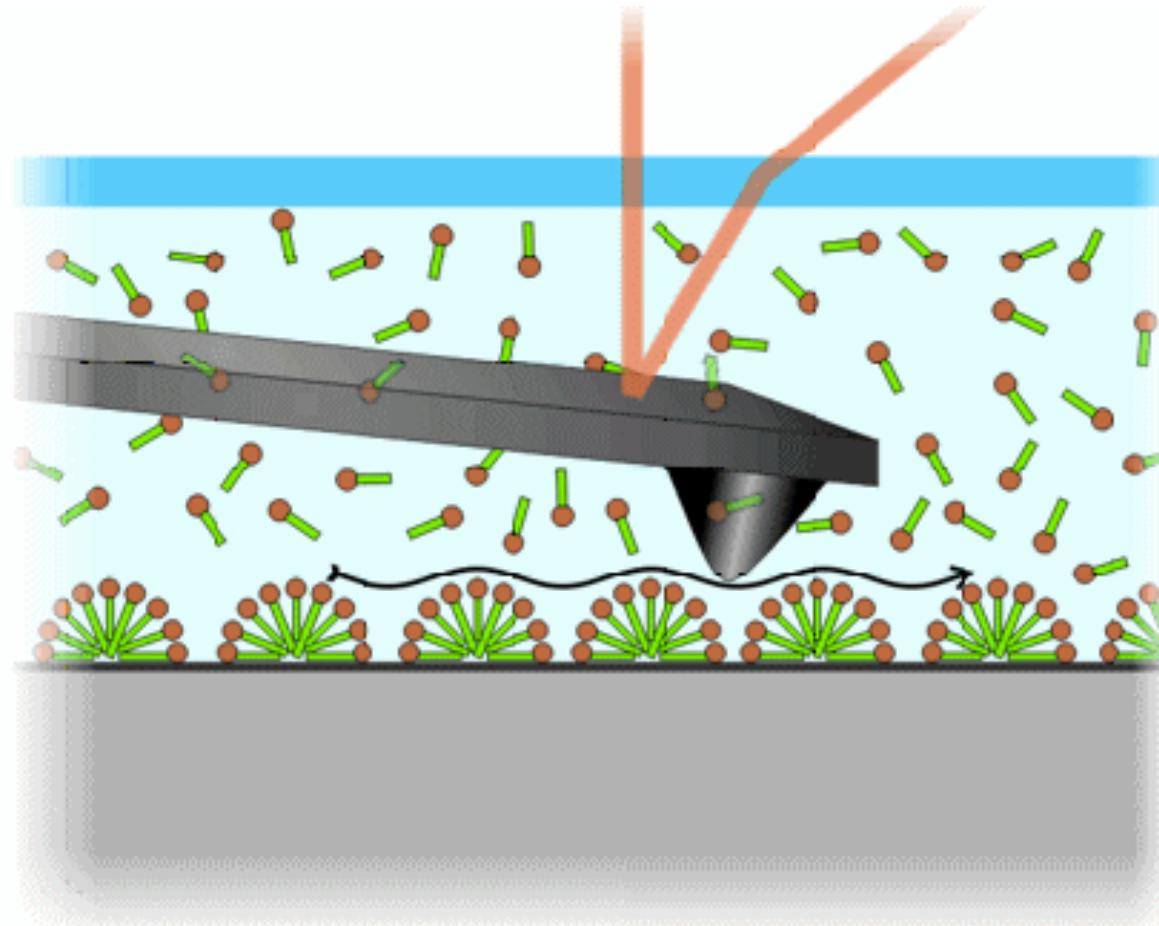


A protein (Reaction Center) located in between a metallic nanogap

(c) S.Carrara

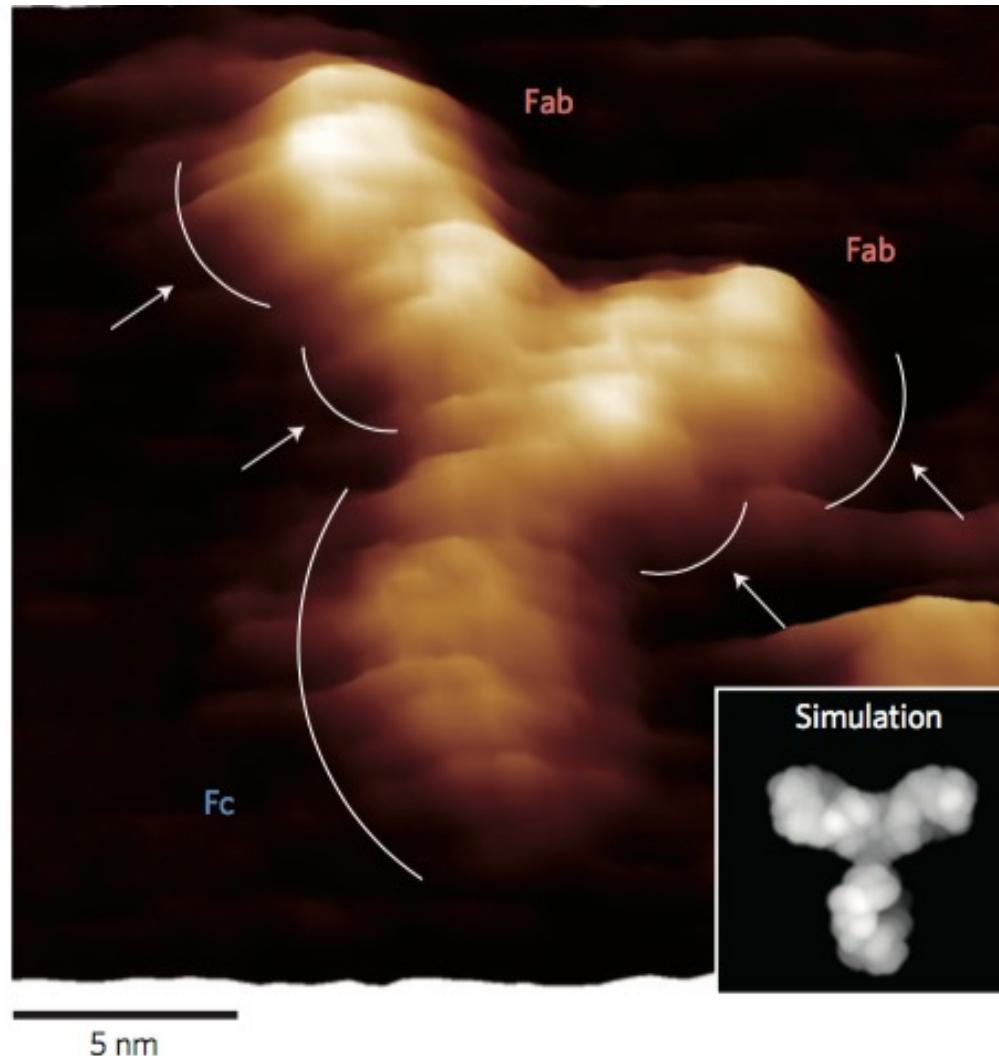
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AFM in liquid



AFM is also used fully in water for imaging typically biological systems in their native environments

AFM Imaging in liquid

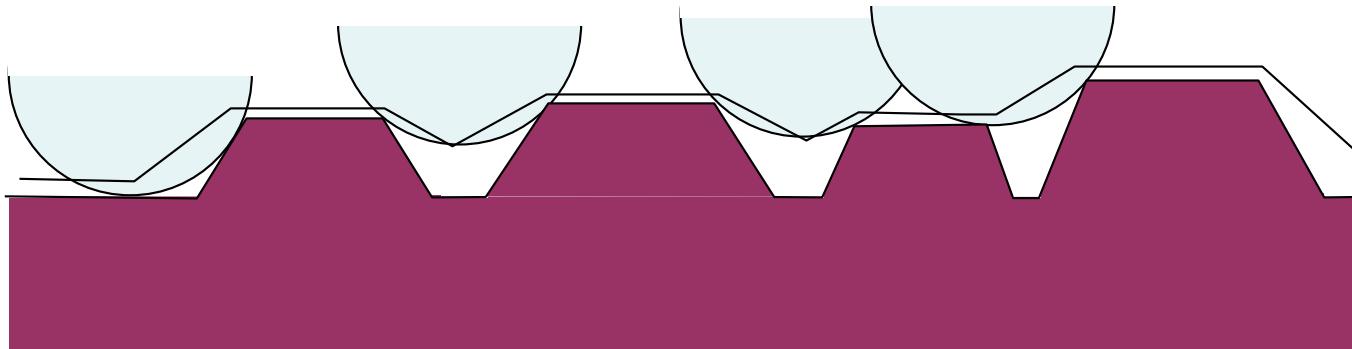


AFM imaging on Antibodies

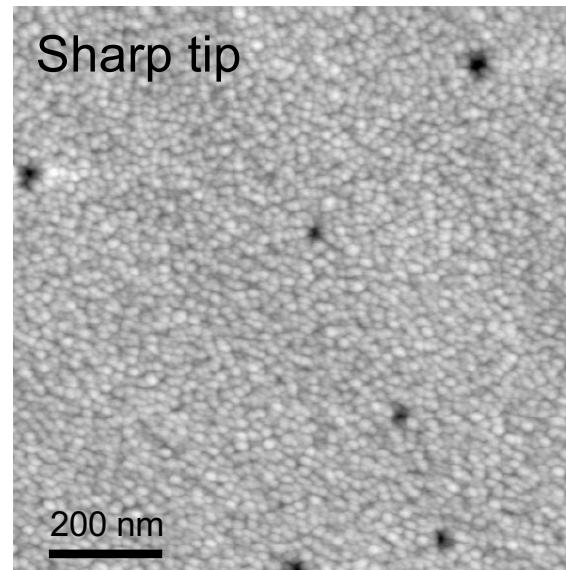
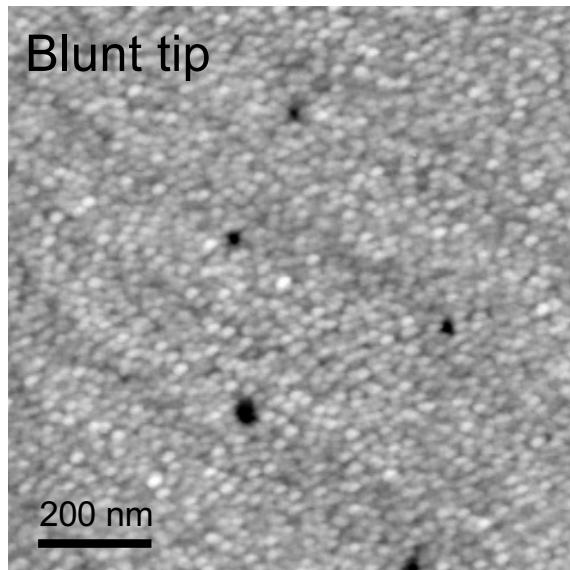
(c) S.Carrara

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Dense nanostructure arrays

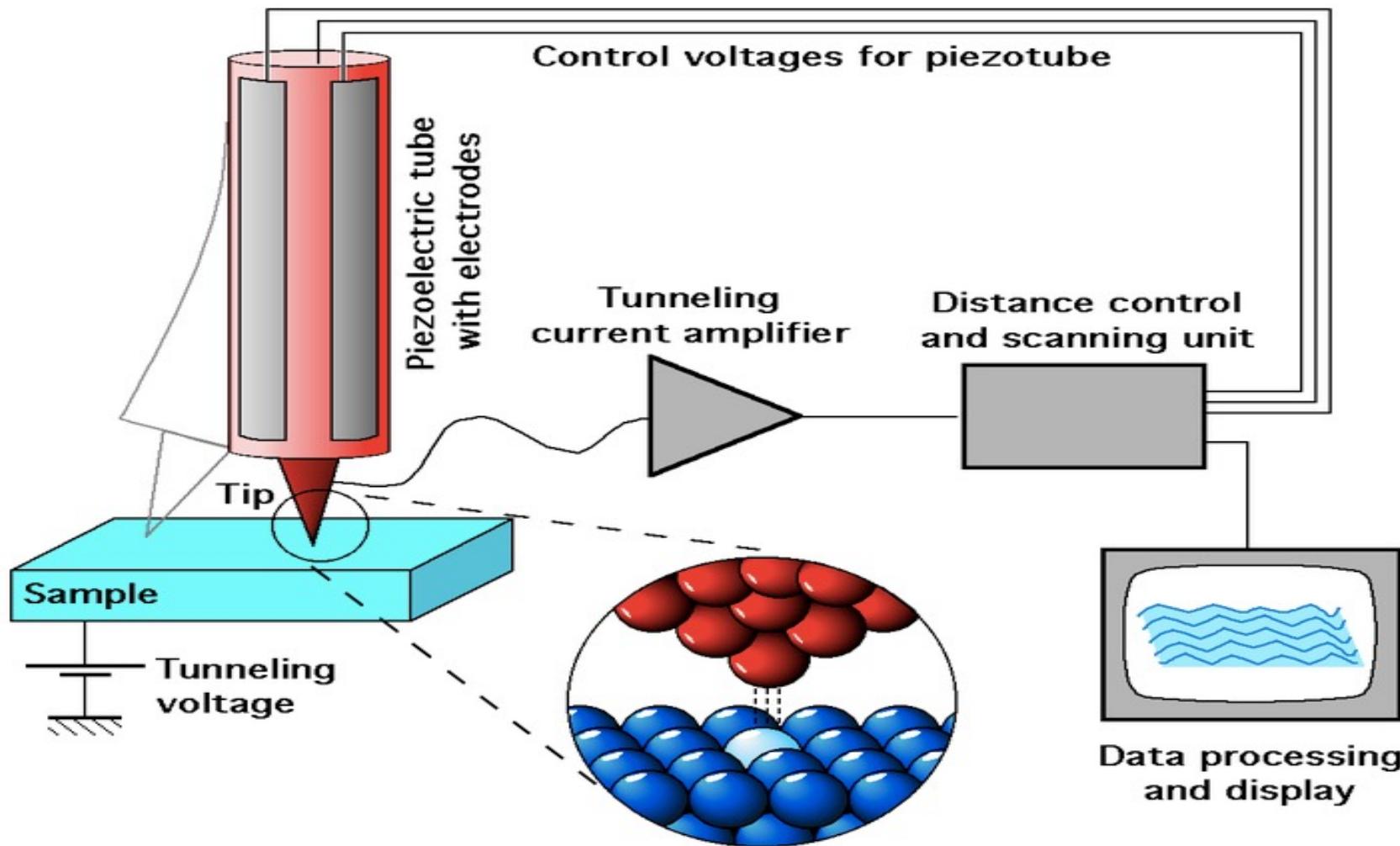


For densely packed features the tip size can also cause errors in determining the height of the islands, or the overall appearance of the surface



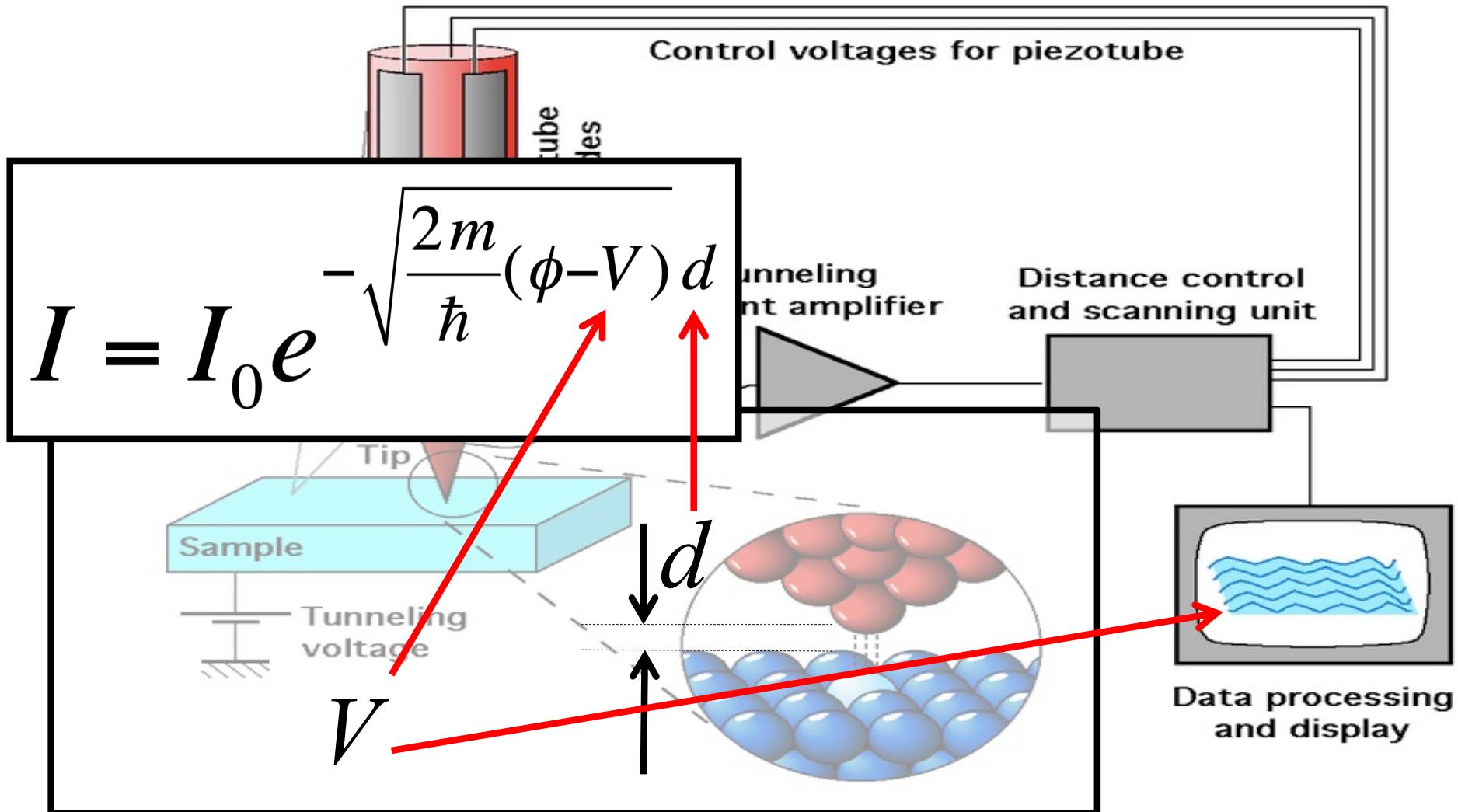
(credit by Cambridge University)

STM Microscopy



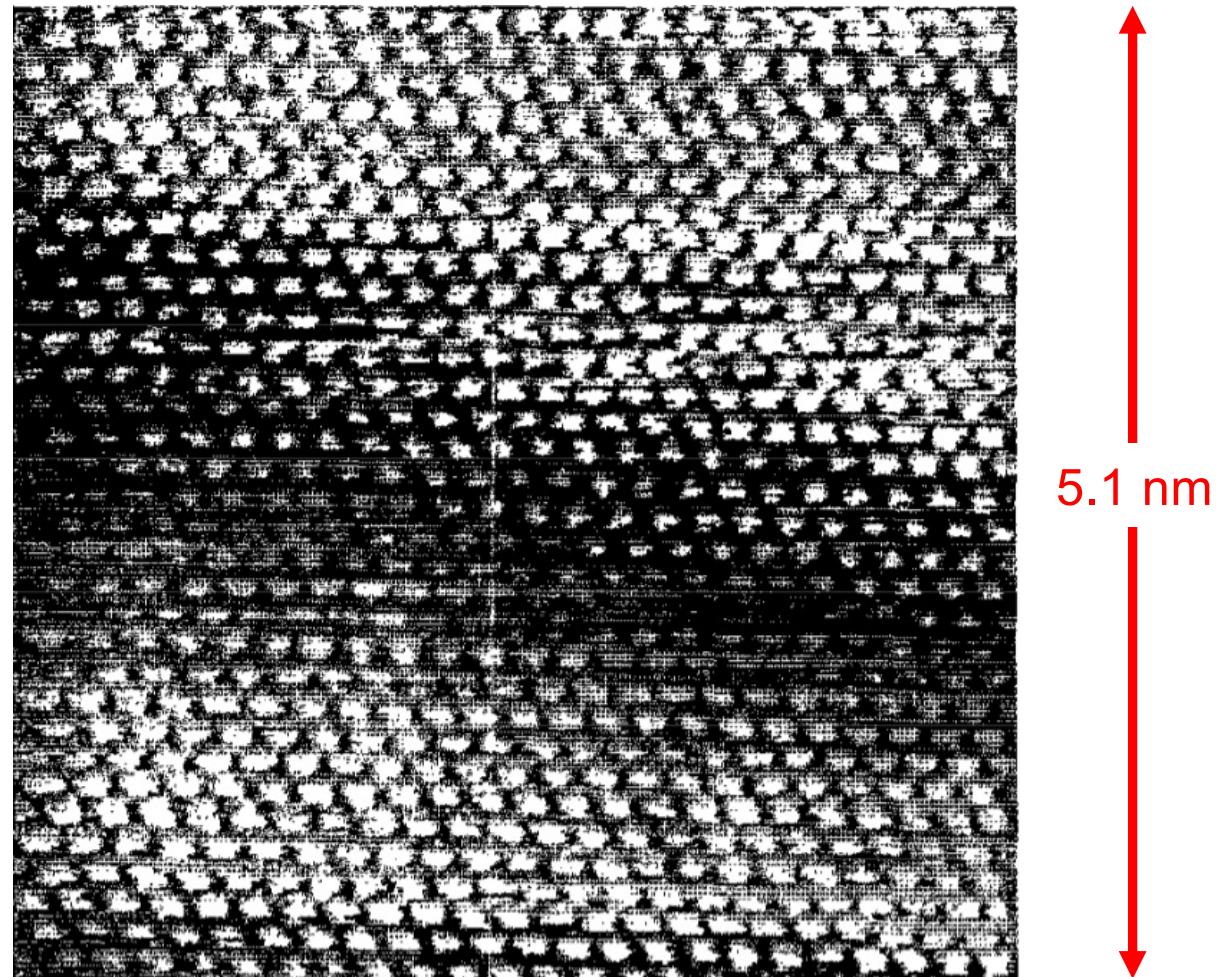
The STM Microscopy is based on tunneling currents as established in between the tip and the sample

STM Microscopy



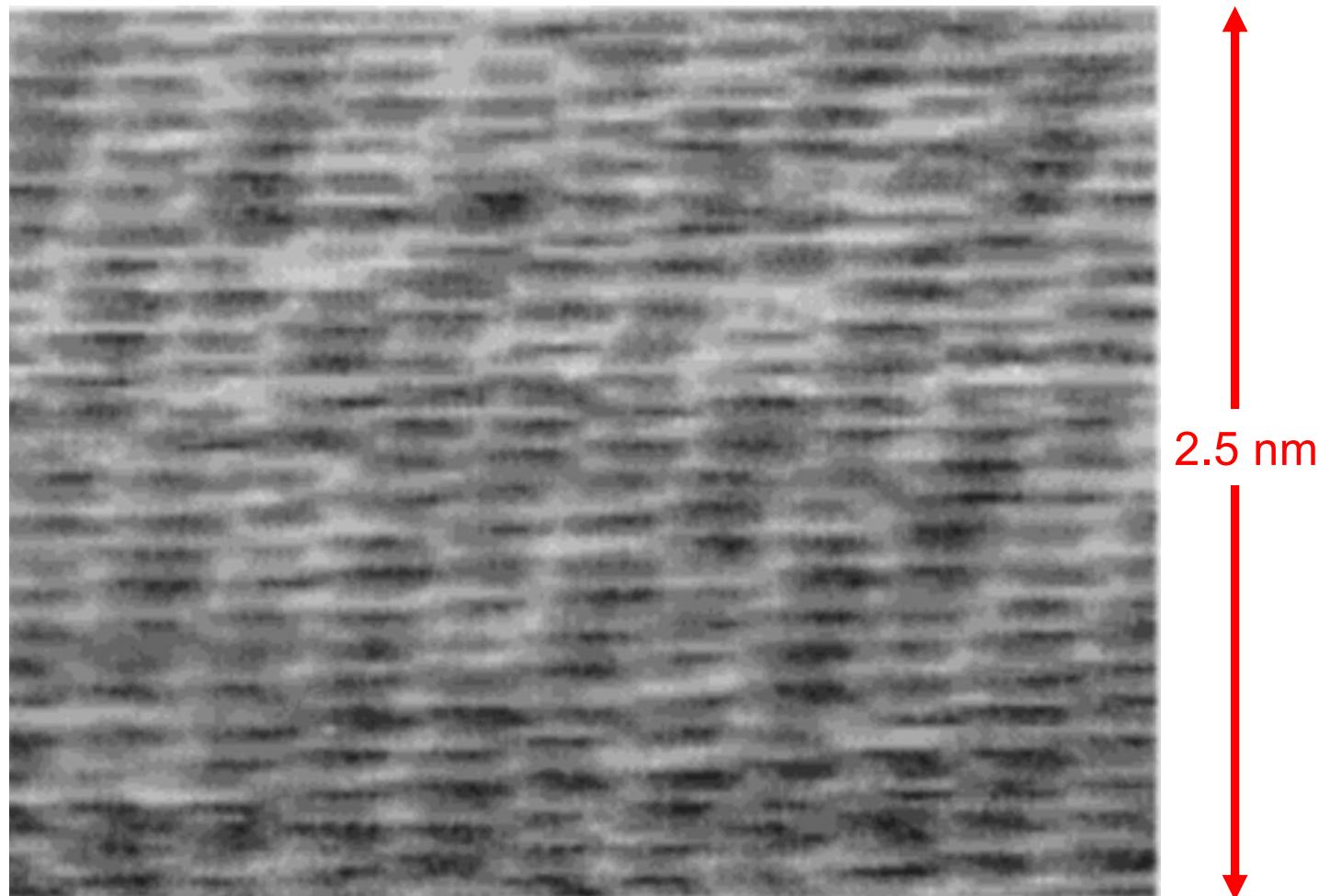
The STM Microscopy is based on tunneling currents as established in between the tip and the sample

STM imaging



Carbon atoms in the lattice structure of the highly oriented pyrolytic graphite. Image by STM in air.

STM imaging



Organic thiols self-assembled onto highly oriented pyrolytic graphite. Image by STM in air.